2019-2020 Semester-II

7H-5C

# Engineering Physics (Theory and lab.)

Instruction Hours/week: L:3T:1P:3

Marks: Internal:40External:60Total:100 End Semester Exam:3 Hours

# (i) Theory Course Objective:

- To inculcate the basics of properties of matter and its applications.
- To study the basics of sound and ultrasonics with appropriate applications.
- To disseminate the fundamentals of thermal and quantum physics and their applications.
- To introduce the concepts of light, laser and fiber optics for diverse applications.
- To impart the basic knowledge of crystal and its various crystal structures.

# **Course Outcomes**

Upon completion of this course, the students will be able

- 1. Develop knowledge on the basics of properties of matter and its applications.
- 2. List the concepts of sound, ultrasonics and their applications.
- 3. Analyse the concepts of thermal properties of materials and advanced physics concepts of quantum theory
- 4. Develop knowledge on the basics of light, laser, fiber optics and their applications.
- 5. Understand the basics of crystals and their structures.
- 6. Apply the knowledge gained from this course to solve the relevant problems in engineering stream.

# **UNIT I - PROPERTIES OF MATTER**

Elasticity: Hooke's law, stress-strain diagram – types of moduli of elasticity – basic definitions, relation connecting the moduli (Derivation)-factors affecting elastic modulus and tensile strength–Poisson's ratio- Torsional pendulum- bending of beams - bending moment – uniform and non-uniform bending - I-shaped girders.

# **UNIT II - ACOUSTICS AND ULTRASONICS**

Classification of sound - loudness and intensity - standard intensity and intensity level - decibel - reverberation- reverberation time- sound absorbing materials - factors affecting acoustics of buildings: focusing, interference, echo, echelon effect, resonance, noise and their remedies. Ultrasonics: production - magnetostriction and piezoelectric methods - industrial applications – Non-destructive testing- pulse echo system through transmission and reflection modes – scan displays.

# **UNIT III - THERMAL AND QUANTUM PHYSICS**

Thermal expansion - thermal stress - expansion joints - bimetallic strips - thermal conductivity- heat conductions in solids – flow of heat through compound media – Forbe's and Lee's disc method: theory and experiment- Introduction to quantum theory – Black body radiation-Laws - dual nature of matter and radiation – de Broglie wavelength, uncertainty principle –Schrödinger's wave equation – time dependent and time independent equations – physical significance of wave function - particle in one dimensional box- degenerate and non-degenerate states.

#### **UNIT IV - APPLIED OPTICS**

Interference - Michelson interferometer: construction, working, determination of wave length and thickness - anti-reflection coating - air wedge and its applications - Lasers – principle and applications – Einstein's coefficients –  $CO_2$  laser - semiconductor lasers: homo junction construction and working, Holography – applications. Optical fibres – classification (index & mode based) principle and propagation of light in optical fibres - acceptance angle and numerical aperture - fibre optic communication system, fibre optic sensors.

# **UNIT V - CRYSTAL PHYSICS**

Single crystalline, polycrystalline and amorphous materials – Single crystals: unit cell, crystal systems, Bravais lattices, directions and planes in a crystal, Miller indices - interplanar distance for a cubic crystal –Effective number, atomic radius, coordination number and packing factor for SC, BCC, FCC, HCP- crystal imperfections: point defects, line defects, surface defects, Burger's vector.

### SUGGESTED READINGS

- 7. Gaur R.K. and Gupta S.L, 2013 Engineering Physics, DhanpatRai Publications.
- 8. PalanisamyP.K, (2006)Engineering Physics, Scitech Publications (P) Ltd.
- 9. ArumugamM, (2000)Engineering Physics, Anuradha Publications.
- 10. SerwayR.A and Jewett J.W, (2010)Physics for Scientists and Engineers with Modern Physics, Thomson Brooks/Cole Publishing Co.
- 11. Tipler P.A. and MoscaG.P, (2007)Physics for Scientists and Engineers with Modern Physics, W.H.Freeman.
- 12. MarkertJ.T., Ohanian, H. and Ohanian M., (2007)Physics for Engineers and Scientists, W.W.Norton& Co.

# (ii) Laboratory

# **Course Objective:**

- To learn the basic concepts in physics relevant to different branches of Engineering and Technology.
- To study the concept of semiconductor and conductivity.
- To learn the properties of materials.

# **Course Outcome:**

1. Familiarize the properties of material and basic concepts in physics.

# LIST OF EXPERIMENTS – PHYSICS

- 1. Torsional pendulum Determination of rigidity modulus of wire and moment of inertia of disc
- 2. Non-uniform bending Determination of young's modulus
- 3. Uniform bending Determination of young's modulus
- 4. Lee's disc Determination of thermal conductivity of a bad conductor
- 5. Potentiometer-Determination of thermo e.m.f of a thermocouple
- 6. Laser- Determination of the wave length of the laser using grating
- 7. Air wedge Determination of thickness of a thin sheet/wire
- 8. Optical fibre -Determination of Numerical Aperture and acceptance angle
- 9. Ultrasonic interferometer determination of the velocity of sound and compressibility of liquids
- 10. Determination of Band gap of a semiconductor.
- 11. Spectrometer- Determination of wavelength using grating.
- 12. Viscosity of liquids-Determination of co-efficient of viscosity of a liquid by Poiseuille's flow



# KARPAGAM ACADEMY OF HIGHER EDUCATION (Deemed to be University Established under Section 3 of UGC Act 1956) COIMBATORE – 641021 FACULTY OF ENGINEERING DEPARTMENT OF SCIENCE AND HUMANITIES LECTURE PLAN

# Subject: ENGINEERING PHYSICSCode: 18BEBME202

Unit No.	List of Topics	No. of Hours
	PROPERTIES OF MATTER	
	Elasticity –Three types of modulus of elasticity	1
	Basic definitions, relation connecting the moduli	1
UNIT I	Factors affecting elastic modulus and tensile strength	1
	Poisson's ratio- Torsional pendulum	1
	Tutorial	1
	Bending of beams - bending moment	1
	Uniform and non-uniform bending	1
	I-shaped girders	1
	Stress due to bending in beams	1
	Tutorial	1
	TOTAL	10
	ACOUSTICS AND ULTRASONICS	
	Classification of sound - loudness and intensity	1
	Standard intensity and intensity level - decibel	1
	Reverberation- reverberation time- sound absorbing materials	1
	Factors affecting acoustics of buildings: focusing, interference,	1
UNIT – II	echo, echelon effect, resonance, noise and their remedies.	
	Tutorial	1
	Ultrasonics: production - magnetostriction and piezoelectric	1
	methods	
	Industrial applications – non-destructive testing	1
	Pulse echo system through transmission and reflection modes	1
	Scan displays	1

	Tutorial	1			
	TOTAL	10			
	THERMAL AND MODERN PHYSICS				
	Thermal expansion - thermal stress - expansion joints	1			
	Bimetallic strips - thermal conductivity- heat conductions in	1			
	solids				
	Flow of heat through compound media	1			
UNIT – III	Forbe's and lee's disc method: theory and experiment	1			
	Tutorial	1			
	Introduction to quantum theory – black body radiation	1			
	Dual nature of matter and radiation – de broglie wavelength	1			
	Uncertainty principle -schrödinger's wave equation - time	1			
	dependent and time independent equations				
	Particle in one dimensional box, physical significance of wave	1			
	function.				
	Tutorial	1			
	TOTAL	10			
	APPLIED OPTICS				
	Interference - Michelson interferometer: construction, working,	1			
	determination of wave length and thickness				
IINIT – IV	Anti-reflection coating - air wedge and its applications	1			
	Lasers – principle and applications – Einstein's coefficients	1			
	Tutorial	1			
	Co <sub>2</sub> laser	1			
	Semiconductor lasers: homo junction construction and working	1			
	– applications				
	Optical fibres – classification (index & mode based) - principle	1			
	and propagation of light in optical fibres				
	Acceptance angle and numerical aperture	1			
	Fibre optic communication system.	1			
	Tutorial	1			
	TOTAL	10			
	CRYSTAL				
	Single crystalline, polycrystalline and amorphous materials	1			
	Single crystals: unit cell, crystal systems, bravais lattices,	1			
	directions and planes in a crystal,				

	Miller indices	1
UNIT – V	Tutorial	1
	Interplanar distance for a cubic crystal	1
	Coordination number and packing factor for sc, bcc,	1
	Coordination number and packing factor for fcc, hcp	1
	Coordination number and packing factor for hcp	1
	Crystal imperfections: point defects, line defects, surface defects	1
	Tutorial	1
	TOTAL	10
	TOTAL NO OF HOURS	50

### **TEXT BOOK& REFERENCES:**

1. Gaur R.K. and Gupta S.L, 2013 Engineering Physics, DhanpatRai Publications,

- 2. Palanisamy P.K, (2006)Engineering Physics, Scitech Publications (P) Ltd,
- 3. ArumugamM, (2000)Engineering Physics, Anuradha Publications,
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Thomson Brooks/Cole Publishing Co.

5. Tipler P.A. and Mosca G.P, (2007)Physics for Scientists and Engineers with Modern Physics,

W.H.Freeman,

6. Markert J.T., Ohanian, H. and Ohanian M., (2007) Physics for Engineers and Scientists,

W.W.Norton& Co.

#### WEBSITES:

- https://www.youtube.com/watch?v=EzcWpOFJ6P4 1.
- 2. https://www.youtube.com/watch?v=x1-SibwIPM4 https://www.youtube.com/watch?v=TcmGYe39XG0
- 3.

#### 4. www.nptel.ac.in

#### STAFF IN-CHARGE

# <u>UNIT 1</u> <u>PROPERTIES OF MATTER</u> <u>PART- A</u>

# **Important Formula's**

 $Stress = \frac{Deforming force}{Area} = \frac{F}{A} \quad (N/m^2)$  $Strain = \frac{Change in dimension}{Original dimension}$ 

Hooke's Law

$$\frac{Stress}{Strain} = E \text{ (constant)}$$

Young's Modulus

$$Y = \frac{Linear \ stress}{Linear \ strain} \qquad (Nm^{-2})$$

Rigidity modulus

$$n = \frac{Tangential \ stress}{Shearing \ strain} \qquad (Nm^{-2)}$$

Bulk modulus

$$K = \frac{Volume \ stress}{volume \ strain} \qquad (Nm^{-2)}$$

Twisting couple per unit twist  $\mathbf{C} = \frac{\pi n \theta r^4}{2l}$ Young's modulus of the cantilever  $\mathbf{Y} = \frac{4Mgl^3}{hd^3 v}$ 

Rigidity modulus of the wire by Torsion pendulum  $n = \frac{16\pi m l (d_2^2 - d_1^2)}{(T_2^2 - T_1^2)r^4} (\text{Nm}^{-2})$ Uniform bending method, Young's modulus of the beam  $\mathbf{Y} = \frac{3}{2} \frac{Mgal^2}{bd^3y} (\text{Nm}^{-2})$ 

Non-Uniform bending method, Young's modulus of the beam

$$\mathbf{Y} = \frac{Mgl^3}{4 bd^3 y} (\mathrm{Nm}^{-2})$$

# 1. Define Stress and its unit.

- The restoring force acting per unit area of the body is called the stress.
- This restoring force is equal and opposite to the applied force F. Therefore, stress is also defined as the applied deforming force per unit area of the body.

Stress = 
$$\frac{Deforming\ force}{Area} = \frac{F}{A}$$
 (N/m<sup>2</sup>)

# 2. What are types of stresses?

It is found that a deforming force may change length or shape or volume of the body. Accordingly, there are three types of stresses namely (i) Linear stress (ii) Shearing Stress (iii) Volume stress.

#### **3.** Define strain and its unit.

- The change in dimension or shape of a body due to the deforming force results in strain.
- It is defined as the ratio of change in dimension to the original dimension.

$$Strain = \frac{Change \ in \ dimension}{Original \ dimension}$$

i.e., strain has no unit.

#### 4. What are types of strains?

According to the changes take place in length, area (shape) and volume, there are three types of strains namely,

- Linear Strain (change in length per unit length)
- Shearing strain (change in area per unit area)
- Volume strain (change in volume per unit volume)

#### 5. State Hooke's Law.

• It states that "within elastic limit, the stress development in the body is directly proportional to the strain produced in it"

Stress  $\infty$  Strain  $\frac{Stress}{strain} = E$  (constant)

> In other words, the ratio between stress and strain is a constant.

#### 6. What are types of Moduli of elasticity?

- > Young's Modulus corresponding to linear strain.
- > Rigidity modulus corresponding to shearing strain.
- > Bulk modulus corresponding to volume strain.

#### 7. Define Young's Modulus of elasticity and mention its unit.

• Within the elastic limit, the ratio of linear stress to linear strain is called Young's modulus of electricity.

$$Y = \frac{Linear \ stress}{Linear \ strain} \quad (Nm^{-2)}$$

#### 8. Define rigidity modulus and mention its unit.

• Within the elastic limit, the ratio of the tangential stress to shearing strain is called rigidity modulus.

$$n = \frac{Tangential \ stress}{Shearing \ strain} \qquad (Nm^{-2)}$$

#### 9. Define Bulk modulus and mention its unit.

• Within the elastic limit of a body, the ratio of volume stress to volume strain is called bulk modulus of elasticity.

$$K = \frac{Volume \ stress}{volume \ strain} \qquad (Nm^{-2})$$

#### 10. What is I Shape Girder?

A girder is a metallic beam supported at its two ends by pillars or on opposite walls. It should be so designed that it should not bend too much or break under its own weight. The cross section of beam is in the form of letter I.

#### 11. What are advantages of I shape girder?

- As the layers of the beam at the upper and bottom are subjected to maximum stress more material must be needed there to withstand the strain.
  - As the stress around the neutral layer is small, material in these regions can be removed without loss of efficiency. This would save economy (cost of material of the girder).
- > This type of cross- section provides a high bending moment and a lot of material is saved.
- ➢ 'I' form of girders are made of steel as they have high young modulus.

#### 12. Define Poisson's ratio.

It is defined as the ratio between the lateral strain per unit stress ( $\beta$ ) to the longitudinal strain per unit stress ( $\alpha$ ), within the elastic limits.

**Poisson's ratio** (
$$\sigma$$
) =  $\frac{lateral strain}{linear strain} = \frac{\beta}{\alpha} = a \text{ constant}$ 

#### 13. List out the factors affecting elasticity.

Some bodies lose their elastic property even within the elastic limit, due to the elastic fatigue. Apart from the fatigue some materials will have change in their elastic property because of the following factors.

1. effect of stress

if a material is subjected to large no.of cycles of stresses, it loses its elastic property even within the elastic limit. Hence working stress should be kept lower than the tensile strengthening and the safety factor.

2. Effect of annealing

Annealing is a process by which the material is heated to a very high temperature and then it is slowly cooled. This will create large crystal size grains, which reduces the elastic property.

3. Change in temperature

Elastic property of the materials changes with the temperature. Normally the elasticity increases with the decrease in temperature and vice-versa.

4. Presence of impurities

The addition of impurities produces variation in the elastic property of the materials. The increase and decrease of elasticity depends on the type of impurity added to it.

5. Nature of crystals.

The elasticity also depends on the types of the crystals, whether it is a single crystal or poly crystals. For a single crystal the elasticity is more and for a poly-crystal the elasticity is less.

#### 14. Draw stress -strain diagram.



# PART – B

#### 1. Derive relations between elastic moduli.

Let us consider n unit cube of a material. Let P,Q and R are the three stresses acting perpendicular to the three faces ABCD, ADHE, and ABFE of the cube.



Each one of the one of these stresses produce an elongation in its own direction and compression along the other two perpendicular direction.

Let  $\alpha$  be the increase in length per unit stress and  $\beta$  be the decrease in length per unit stress.

The elongation along the direction  $P = \alpha P$ 

The contraction along the direction P due to stress  $Q = \beta Q$ 

The contraction along the direction P due to stress  $R = \beta R$ 

The net elongation along the direction  $P = e = \alpha Q - \beta P - \beta R$  ------ 1

The net elongation along the direction  $Q = f = \alpha P - \beta Q - \beta R$  ------ 2

The net elongation along the direction  $R = g = \alpha R - \beta P - \beta Q$  ------ 3

We can express the three elastic constants, Y,K and n in terms of  $\alpha$  and  $\beta$  as follows.

#### **Condition1.**

If only the stress 'P' acts and Q=R=0 Substitute this in equation 1 Linear strain e = αP

**Youngsmodulus**  $\mathbf{Y} = \frac{stress}{linear strain} = \frac{P}{\alpha P} = \frac{1}{\alpha}$ 

$$\alpha = \frac{1}{Y} - --- 4$$

#### **Condition 2.**

If all stress and equal P=Q=RSubstitute this in equation 1 strain  $e = (\alpha - \beta - \beta)P = (\alpha - 2\beta)P$  ------5 From the standard relation, volume strain is equal to 3e Volume strain = 3 ( $\alpha$ -2 $\beta$ )P

**Bulk modulus K** =  $\frac{Bulk \ stress}{Bulk \ strain} = \frac{P}{3(\alpha - 2\beta)P}$ 

$$\alpha - 2\beta = \frac{1}{3K} - --- 6$$

#### **Condition 3.**

Suppose the P=-Q and R=0 Substitute this in equation 1 strain  $e = \alpha P - \beta(-P) = (\alpha + \beta)P$  -----7 From the standard relation, angle of shear ad strain, Shearing strain  $\phi = 2e$ Substituting value of e from eqn. 7  $\phi = 2 (\alpha + \beta)P$  -------8

**Rigidity modulus n** =  $\frac{Tangential stress}{Shearing strain} = \frac{P}{\phi}$ 

$$n = \frac{P}{2(\alpha + \beta)P} = \frac{1}{2(\alpha + \beta)}$$

$$\alpha + \beta = \frac{1}{2n} - 9$$

# 1. Relation between Y, n and K

From eqn. 9

$$\alpha + \beta = \frac{1}{2n}$$

$$2\alpha + 2\beta = \frac{1}{n}$$
-----10

Adding equ. 10 and 6

$$3\alpha = \frac{1}{n} + \frac{1}{3K}$$
$$\alpha = \frac{1}{3} \left[ \frac{3K + n}{3Kn} \right]$$
------11

Equation eqn. 4 and 11 we have

$$\frac{1}{Y} = \frac{3K+n}{9Kn}$$
$$Y = \left[\frac{9Kn}{3K+n}\right]$$
------12

2. Relation between n, K and  $\sigma$ 

$$3\beta = \frac{1}{2n} - \frac{1}{3K}$$
$$3\beta = \frac{3K - 2n}{6Kn} \quad -----13$$
$$\beta = \frac{3K - 2n}{18Kn}$$

Substituting for  $\alpha$  and  $\beta$  from eqn. 11 and 13 in poisons ratio

$$\sigma = \frac{\frac{3K - 2n}{18Kn}}{\frac{9Kn}{3K + n}} = \frac{3K - 2n}{6K + 2n} - 14$$

#### 3. Relation between Y, n and $\sigma$

Dividing eqn. 9 by 4 we have

$$\frac{\alpha + \beta}{\alpha} = \frac{\frac{1}{2n}}{\frac{1}{Y}}$$

$$1 + \frac{\beta}{\alpha} = \frac{Y}{2n}$$

$$1 + \sigma = \frac{Y}{2n} - 1$$

$$\sigma = \frac{Y}{2n} - 1$$

#### 2. Derive an expression for the twisting couple on a wire.

Consider a cylindrical wire of length l and radius r fixed at one end. It is twisted through an angle θ by applying couple to its lower end. Now, the wire is said to be under torsion.



- Due to elastic Property of the wire, an internal restoring couple is set up inside the wire. It is equal and opposite to the external twisting couple (applied).
- The cylinder is imagined to consist of a large number of thin hollow coaxial cylinders.
- Consider one such cylinder of radius x and thickness dx.
- AB is a line parallel to PQ on the surface of this cylinder. As the cylinder is twisted, the line AB is shifted to AC through an angle BAC =  $\Phi$

Shearing strain or Angle of shear =  $\Phi$ 

Angle of twist at the free end =  $\theta$ 

From the figure (1.11 (b))

BC = 
$$x\theta = l\Phi$$
  
 $\Phi = \frac{x\theta}{l}$  -----(1)

Rigidity modulus  $n = \frac{S hearing Strees}{Shearing strain}$ 

Shearing stress = n x Shearing strain =  $n\Phi$ 

$$=\frac{nx\theta}{l}$$

But, Shearing stress =  $\frac{Shearing force}{Area over Which the force act}$ 

Shearing force = Shearing stress X area over which the force acts

area over which the force acts =  $\pi (x + dx)^2 - \pi^2$ =  $\pi (x^2 + 2xdx + dx^2) - \pi x^2$ =  $\pi x^2 + 2\pi x dx + \pi dx^2 - \pi x^2$ ( $dx^2$  term is neglected since it is very small) =  $2\pi x dx$ 

Hence, shearing force  $F = \frac{nx\theta}{l} 2\pi x dx$ 

$$= \frac{2\pi n\theta}{l} x^2 dx - (2)$$

The moment of this force about the axis PQ of the cylinder.

= Force X Perpendicular distance

$$= \frac{2\pi n\theta}{l} x^2 dx \quad X \quad x$$
$$= \frac{2\pi n\theta}{l} x^3 dx - \dots (3)$$

The moment of the force acting on the entire cylinder of radius r is obtained by integrating the expression (3) between the limits x = 0 and x = r.

Hence ,twisting couple

$$C = \int_0^r \frac{2\pi n\theta}{l} x^3 dx$$

$$\frac{2\pi n\theta}{l} \int_0^r x^3 dx = \frac{2\pi n\theta}{l} \left[ \frac{x^4}{4} \right]$$

Applying the units ,we have

$$=\frac{2\pi n\theta}{l}\left[\frac{r^4}{4}-0\right]$$

$$\mathbf{C}=\frac{\pi n\theta r^4}{2l}$$

This twisting couple required to produce a twist of unit radian in the cylinder is called torsional **rigidity for material of the cylinder.** 

Hollow Cylinder :

For a hollow cylinder of the same length l and of inner radius  $r_1$  and outer radius  $r_2$ 

$$C = \int_{r_1}^{r_2} \left(\frac{2\pi n\theta}{l}\right) x^3 dx$$
$$= \left(\frac{\pi n\theta}{2l}\right) \left(r_2^4 - r_1^4\right)$$

Twisting couple per unit twist of the cylinder

$$\mathbf{C} = \frac{\pi n}{2l} \left( r_2^4 - r_1^4 \right)$$

- **3.** Define torsional pendulum. Give theory of this pendulum. How it is used to find the rigidity modulus of the wire.
  - A circular metallic disc suspended using a thin wire that executes torsional oscillation is called torsional pendulum.

# **Description**

• A torsional pendulum consists of a metal wire suspended vertically with the upper end fixed. The lower end of the wire is connected to the centre of a heavy circular disc.



When the disc is rotated by applying a twist, the wire is twisted through an angle  $\theta$ . Then, the restoring couple set up in the wire

 $= C\theta$  ----(1)

If the disc is released, it oscillates with angular velocity  $\frac{d\theta}{dt}$  in the horizontal plane about the axis of the wire. These oscillations are known as torsional oscillations.

Applied couple = 
$$I \frac{d^2\theta}{dt^2}$$
---(2)

In equilibrium, applied couple = restoring couple

Hence, the motion of the disc being simple harmonic motion, the time period of the oscillation is given by

$$T = 2\pi \sqrt{\frac{Displacement}{Acceralation}}$$

$$=2\pi\sqrt{\frac{\theta}{\frac{C}{I}X\theta}}$$

$$\mathbf{T} = 2\pi \sqrt{\frac{l}{c}} - (4)$$

### **Experiment**

- A circular disc is suspended by a thin wire, whose rigidity modulus is to be determined. The top end of the wire is fixed firmly in a vertical support.
- The disc is then rotated about its centre through a small angle and set it free. It executes torsional oscillations.
- The time taken for 20 complete oscillations is noted. The experiment is repeated and the mean time period (T) of oscillation is determined.
- The length L of the wire is measured. This length is then changed by about 10 cm and then the experiment is repeated. The readings for five or six different lengths of wire are measured.

The disc is removed and its mass and diameter are measured.

The time period of oscillation is

Squaring on both sides, we have

T<sup>2</sup>= 
$$2^2 \pi^2 \left[ \sqrt{\frac{I}{c}} \right]$$
 ---- (2)  
T<sup>2</sup> =  $\frac{4\pi^2}{c}$  I ---- (3)

Substituting couple per unit twist  $C = \frac{\pi n r^4}{2l}$  in eqn (4),

We have

$$T^{2} = \frac{4\pi^{2} I}{\frac{\pi n^{4}}{2l}} = \frac{2l X 4\pi^{2}}{\pi n r^{4}}$$

Rearranging the equation (5)

The rigidity modulus of the material of the wire

$$n = \frac{8\pi I l}{r^4 T^2}$$

where

M - Mass of the circular disc

R - Radius of the disc.

# **Rigidity modulus by Torsion Pendulum (Dynamic torsion method)**

The torsion pendulum consists of a steel or brass wire with one end fixed in an adjustable chuck and the other end to the centre of a circular disc as shown in figure.



The experiment consists of three parts.

First the disc is set into torsional oscillations without any cylindrical masses on the disc. The mean period of oscillation  $'T_o'$  is found out.

$$T_0 = 2\pi \sqrt{\frac{I_0}{c}}$$

Where  $I_0$  - moment of inertia of the disc about the axis of the wire.

$$T_0^2 = 4\pi^2 \frac{I_0}{c} - ---(1)$$

Two equal cylindrical masses (each mass m equal to 200 gm) are placed symmetrically along a diameter of the disc at equal distance  $d_1$  on the two sides of the centre of the disc.

Mean time period of Oscillation  $T_1$  is found.

Then, 
$$T_1 = 2\pi \sqrt{\frac{I_1}{c}}$$

$$T_1^2 = 4\pi^2 \frac{I_1}{c} - \dots - (2)$$

Then, by the parallel axis theorem, the moment of inertia of the whole system is given by

$$I_1 = I_0 + 2i + 2m d_1^2 - \dots (3)$$

Substituting the value of  $I_1$  in eqn. (2)

$$T_1^2 = \frac{4\pi^2}{c} (I_0 + 2i + 2m d_1^2)$$
 ---- (4)

Mean time period of oscillation  $T_2$  ' is found out in this case also.

$$T_2 = 2\pi \sqrt{\frac{I_2}{c}}$$
  
$$T_2^2 = 4\pi^2 \frac{I_2}{c}$$
 (I\_2 = I\_0 + 2i + 2m d\_2^2)

$$T_2^2 = \frac{4\pi^2}{C} (I_0 + 2i + 2m d_2^2)$$
 ---- (5)

Now,

$$I_2$$
-  $I_1 = I_0 + 2i + 2m d_2^2 - I_0 - 2i - 2m d_1^2 = 2m(d_2^2 - d_1^2)$   
Subtracting (4) from (5), We have

$$T_{2}^{2} - T_{1}^{2} = \frac{4\pi^{2}}{c} [I_{0} + 2i + 2m d_{2}^{2} - I_{0} - 2i - 2m d_{1}^{2}]$$
$$= \frac{4\pi^{2}}{c} 2m(d_{2}^{2} - d_{1}^{2})$$
$$= \frac{4\pi^{2}}{c} (I_{2} - I_{1}) \qquad ----- (6)$$

Dividing eqn.(1) by eqn.(6)

$$\frac{T_0^2}{T_2^2 - T_1^2} = \frac{I_0}{I_2 - I_1}$$
(7)

Substituting the value of  $(I_2-I_1)$  in this equation (7), we have

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$$\frac{T_0^2}{T_2^2 - T_1^2} = \frac{I_0}{2\mathrm{m}(d_2^2 - d_1^2)}$$

$$I_0 = \frac{2m(d_2^2 - d_1^2)}{T_2^2 - T_1^2} \ T_0^2$$

# Calculation of rigidity modulus of the wire

We know that restoring couple per unit twist

$$C = \frac{\pi n r^4}{2l} - \dots - (8)$$

Substituting the value of C in expression (6) we have

$$T_2^2 - T_1^2 = \frac{4\pi^2}{\frac{\pi n r^4}{2l}} 2m(d_2^2 - d_1^2)$$
$$= \frac{4\pi^2}{\pi n r^4} 2l \times 2m(d_2^2 - d_1^2)$$
$$= \frac{16\pi m l(d_2^2 - d_1^2)}{n r^4}$$

$$\boldsymbol{n} = \frac{16\pi m l (d_2^2 - d_1^2)}{(T_2^2 - T_1^2) r^4} \dots (9)$$

### 4. Derive an expression for bending of a beam.

Let us consider a beam under the action of deforming forces. The beam bends into a circular arc. Let AB are elongated and the filaments below AB are compressed. The filament AB remains unchanged.



Let PQ be the arc chosen from the neutral axis. If R is the radius of curvature of the neutral axis and  $\theta$  is the angle suspended by it as its centre of curvature C.

Tensile force on the area  $\delta A = \text{stress } x$  area

Tensile force =  $\frac{Yx}{R} \delta A$ 

Moment of force = Force x perpendicular distance

Moment of force about the neutral axis AB OR PQ =  $\frac{Y_x}{R} \delta A$ . x

$$PQ = \frac{Y}{R} \delta A. x^2$$

The moment of force acting on both the upper and lower halves of the neutral axis can be got by summing of tensile and compressive forces about the neutral axis.

The moment of all the forces about neutral axis =  $\frac{Y}{R} \Sigma x^2 \delta A$ .

 $I_g = \Sigma x^2 \delta A = AK^2$  is called as the geometrical moment of inertia. Where, A is the total area of the beam, K is the radius of gyration.

Total moment of all the forces or internal bending =  $\frac{YI_g}{R}$ 

#### Case i. Rectangular cross-section

If b is the breadth and d is the thickness of the beam,

Area A = bd  

$$K^{2} = \frac{d^{2}}{12}$$

$$\therefore I_{g} = AK^{2} = \frac{bd \cdot d^{2}}{12} = \frac{bd^{3}}{12}$$

Substituting value of  $I_g$  in eqn. 6 , We can write

Bending moment for a rectangular cross section =  $\frac{Ybd^3}{12R}$  -----7

### Case ii.Circular cross-section

If r is the radius of rod,  $A = \pi r^2$ 

$$K^{2} = \frac{r^{2}}{4}$$
  
 $\therefore I_{g} = AK^{2} = \frac{\pi r^{2} r^{2}}{4} = \frac{\pi r^{4}}{4}$ 

Substituting value of  $I_g$  in eqn. 6 , We can write

Bending moment for a circular cross section =  $\frac{\pi Y r^4}{4R}$  ------8

5. What is uniform bending? Derive an expression for the elevation at the centre of a beam which is loaded at the both ends. Describe an experiment to determine Young's modulus of a beam by uniform bending.

#### Definition:

If the beam is loaded uniformly on its both ends, bending of the beam forms an arc of a circle. The elevation is produced in the beam. This type of bending is known as uniform bending.

#### Theory:

- Consider a beam AB arranged horizontally on two knife- edges C and D symmetrically.
- > The beam is loaded with equal weights W at each ends A and B.
- The reaction on the knife edges at C and D are equal to W and they are acting vertically upward.



External bending moment on the part AF

-----(2)

Internal bending moment=  $\frac{YI}{R}$ 

- Y Young's modulus of the beam
- I Geometrical moment of inertia
  - R Radius of curvature of the beam

In the equilibrium position,

Wa = 
$$\frac{YI}{R}$$
-----(3)

Then, from the property of a circle

EF x EG = CE x ED  

$$Y (2R-y) = \left(\frac{l}{2}\right)^{2}$$

$$2yR - y^{2} = \frac{l^{2}}{2^{2}} = \frac{l^{2}}{4}$$

$$y2R = \frac{l^{2}}{4}(y^{2} - is negligible)$$

$$y = \frac{l^{2}}{8R}$$

$$\frac{1}{R} = \frac{8y}{l^{2}} - \cdots - (5)$$

Substituting the eqn (5) in (3), we have

Wa= $\frac{8y}{l^2}$ YI

$$Y = \frac{Wal^2}{8ly} - \dots - (6)$$

If the beam is rectangular section,

I = 
$$\frac{bd^3}{12}$$

The corresponding weight,

$$W = Mg$$

Substituting for W and I in egn (6), we have

$$Y = \frac{Mgal^2}{8\frac{bd^3}{12}y}$$

$$\mathbf{Y} = \frac{3}{2} \frac{Mgal^2}{bd^3y}$$

# **Experiment**

- A rectangular beam AB of uniform section is supported horizontally on two knife-edges A and B.
- Two weight hangers of equal masses are suspended from the ends of the beam. A pin is fixed vertically at the mid-point of the beam. A microscope is focused on the tip of the pin.



- Initial reading in the microscope in the vertical scale is noted. Equal weights are added to both hangers simultaneously and the reading in the microscope on the vertical scale is noted.
  - $\circ$  The experiment is repeated for decreasing order of the equal masses.
  - The observations are tabulated and mean elevation (y) at the midpoint of the bar is determined.

- The length of the bar between the knife edges 'l' is measured. The distance of the one of the weight hangers from the nearest knife edge 'a' is measured.
- The breadth (b) and thickness (d) of the bar are measured by using vernier calipers and screw gauge.

	Microscope Readings			
	Loading	Un – loading	Mean	Depression
Load (gm)	cm		(cm)	(y)
W				
W+50				
W+100				
W+150				
W+200				
W+250				
		· · · · · · · · · · · · · · · · · · ·	Mean	

> Young's modulus of the beam is determined by the relation.

$$\mathbf{Y} = \frac{3}{2} \frac{Mgal^2}{bd^3y}$$

6. Describe with necessary theory , the method of determining the Young's modulus of the material of the beam if rectangular cross-section by bending it non-uniformly.

# **NON - UNIFORM BENDING**

- If the beam is loaded at its mid-point, the depression produced does not form an arc of a circle. This type of bending is called non-uniform bending.
- Consider a uniform cross sectional beam (rod or bar) AB of length l arranged horizontally on two knife edges K<sub>1</sub> and K<sub>2</sub>near the ends A and B.



- A weight W is applied at the midpoint 'O' of the beam. The reaction force at each knife edge is equal to  $\frac{W}{2}$  in the upward direction. y is the depression at the mid point O.
- The bent beam is considered to be equivalent to two inverted cantilevers, fixed at O each of Length  $\frac{l}{2}$  and each loaded at K<sub>1</sub> and K<sub>2</sub> with a weight  $\frac{W}{2}$

In the case of a cantilever of length l and load W, the depression  $=\frac{Wl^3}{3Iy}$ Hence, for cantilever of length  $\frac{l}{2}$  and load  $\frac{W}{2}$  depression is

$$y = \frac{\left(\frac{W}{2}\right)\left(\frac{l}{2}\right)^3}{3Iy}$$
$$y = \frac{Wl^3}{48IY}$$

If M is the mass, the corresponding weight W is

$$W = Mg$$

If the beam is a rectangular,  $I = \frac{bd^3}{12}$  where b is the breadth and d is the thickness of the beam.

Hence,

$$Y = \frac{Mgl^3}{48\frac{bd^3y}{12}}$$
$$= \frac{12 Mgl^3}{48 bd^3y}$$

$$\mathbf{Y} = \frac{Mgl^3}{4 \ bd^3y}$$

The value of Y can be determined by the above equation.

# **Experiment**

• The given beam AB of rectangular cross section is arranged horizontally on two knife edges K<sub>1</sub> and K<sub>2</sub> near the ends A and B.



- > A weight hanger is suspended and a pin is fixed vertically at mid-point O.
- > A microscope is focussed on the tip of the pin.

- The initial reading on the vertical scale of the microscope is taken. A suitable mass M is added to the hanger. The beam is depressed. The cross wire is adjusted to coincide with the tip of the pin. The reading of the microscope is noted.
- The depression corresponding to the mass M is found.
- The experiment is repeated by increasing and decreasing the mass step by step. The corresponding readings are tabulated. The average value of depression y is found from the observation
- > The breadth b, thickness d and length L of the beam are measured.

	Microscope Readings			
	Loading	Un – loading	Moon	Depression
Load	cn	n	(cm)	(y)
(gm)	CIII			
W				
W+50				
W+100				
W+150				
W+200				
W+250				
			Mean	

> The value of Young's modules of the beam is found by the relation.

$$\mathbf{Y} = \frac{Mgl^3}{4 \ bd^3y}$$

# Appendix

#### What is cantilever? Derive an expression for depression at the free end of cantilever.

#### CANTILEVER

> cantilever is a beam fixed horizontally at one end and loaded at the other end

Under equilibrium condition,

External bending moment = Internal bending moment

# DEPRESSION OF A CANTILEVER-LOADED AT ITS ENDS THEORY:

Consider a cantilever of length 1 fixed at the end A and loaded at the free end B by a weight W. The end B depressed to B<sup>1</sup>. AB is the neutral axis.

> Consider the section of the cantilever P at a distance x from the fixed end A. It is at distance (l-x) from the loaded end  $B^1$ .



The external bending moment = W(*l*-*x*)

The internal bending moment =  $\frac{YI}{R}$ 

Under Equilibrium condition,

External bending moment = Internal bending moment Therefore,

W 
$$(l-x) = \frac{YI}{R}$$
 (1)

Q is the another point at a distance dx from P

$$PQ = dx = R d\theta \qquad -----(2)$$

Vertical depression,

 $dy = (1-x) d\theta$  ------(3)

From the eqns (2) and (3), we have

Substituting for R in eqn (1), we have

W (*l-x*) = 
$$\frac{YI \, dy}{(l-x)dx}$$
 -----(5)

Rearranging eqn (5), we have

dy 
$$= \frac{W}{YI} (l - x) (l - x) dx$$
  
dy  $= \frac{W}{YI} (l - x)^2 dx$  -----(6)

Total deperssion y at the free end is

$$\int dy = \int_0^l \frac{W}{YI} (1-x)^2 dx -...(7)$$
$$y = \frac{W}{YI} \int_0^l (l-x)^2 dx$$

$$y = \frac{W}{YI} \int_{0}^{l} (l^{2} + x^{2} - 2lx) dx$$

$$y = \frac{W}{YI} \left[ l^{2}x + \frac{x^{3}}{3} - \frac{2lx^{2}}{2} \right] dx$$

$$y = \frac{W}{YI} \left[ l^{3} + \frac{l^{3}}{3} - l^{3} \right] dx$$

$$y = \frac{W}{YI} x \frac{l^{3}}{3}$$

$$y = \frac{Wl^{3}}{3YI} \qquad -----(8)$$

Determination of Young's modulus of the cantilever

Depression for the free end of the cantilever

$$\mathbf{y} = \frac{Wl^3}{3YI}$$

Young's modulus of the cantilever

$$\mathbf{Y} = \frac{Wl^3}{3Iy}$$
-----(9)

For a beam of rectangular cross-section,

$$I = \frac{bd^3}{12}$$

Where b is the breadth and d thickness of the beam.

The weight W = Mg

Where M is the mass suspended at the free end and g is acceleration due to gravity.

Substituting for W and I in egn (9), we have

$$Y = \frac{Mgl^3}{3\frac{bd^3y}{12}}$$
$$= \frac{Mgl^3}{\frac{bd^3y}{4}}$$
$$Y = \frac{4Mgl^3}{bd^3y}$$

# Experimental determination of young s modulus of a cantilever:

- The given bar is fixed rigidly at one end and a weight hanger is suspended at the other end.
- A pin is fixed vertically at the free end of the beam. A travelling microscope is focused on the pin. The microscope is adjusted such that the horizondal crosswire coincides with the tip of the pin. The initial reading in the microscope on the vertical is noted.
- A suitable mass M is placed on the hanger. The reading in the microscope is again noted. The difference between two readings of the microscope gives the depression y corresponding to load M.


- The experiment is repeated by increasing the values of M in the steps of 50 gm. Then, the experiment is also repeated by decreasing the weights.
- > The length l of the beam, its breadth b and thickness d are measured.

	Microso	cope Readings		
	Loading	Un – loading	Mean	Depression
Load	cm	י ז	(cm)	(y)
(gm)	CII	1	(em)	
W				
W+50				
W+100				
W+150				
W+200				
W+250				
			Mean	

> Young's modulus of the beam is determined by the relation.

$$\mathbf{Y} = \frac{4Mgl^3}{bd^3y}$$

UNIT- II Sound & ultrasonies classification of sound. Sound Andille range of Frequency above Frequery below 20,000 HZ bequency 20 HZ Ultrasonics 20-2000HZ Infrasmies noise Music

Characteristics of nuesical sound

(1) pitch: Sticke characteristic of Sound which is the sensation conveyed to our brain by the Sound waves falling in our eases. It depends on the frequency of incident sound waves. frequency - physical quantity, Pitch, physiological quantity in Quelity or Timbre

This helps us to distiguish setures musical notes entitled by different musical instruments, voices, eventhough they have the same sitch and loudness. Siij Intensity or Ludness:

The average rate of flow of accoustic energy (Q) per unit area situated normally to the direction

of propagation of Sound wave. n -> frequency of sound t = ala a & amplitude of a IX hia PV P I density of the medium Intersity / unit area/ unit the × -> distance from Source to desteration  $I = 2\pi t_a z_h L_{pv}$ 

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Loudrey It is defined as the degree of servation produced on the east louisess varies from me down to another It is a physiological quantity and it is difficult to measure soulests. Logarsthric value of intensity L & Log I L = he log I ~ D ween Fechier las Sifferenticking egn @  $\frac{dL}{dt} = \frac{k}{t}$ dL is sensitiveness of ear I deceased with the increase is interest. Intensity Londrem - just a sensation pro build - Refers to external measurement + It is common to hear + It dyends on Individual modured listerer. + measued flight bespect + It can be measured directly to intensity.

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Units of loudness

If I, is the Loudness of sound of Intensity I, and Lo is the Loudness Corresponding to the standard reference intensity Io= 10-12 W/m2 Mpply weber fectiver Law, In= K Losio I, Lo = K Logio Io tf IL = IL, -Lo = KLS10 I, - KLS10 IO I these I If lezi Ic = 1 + Les 10 I bet bel- unit haved after Alexander Smalambell. Decisel The cerit 'sel' is quite Large and here In is expressed by another Standard unit called decisel 1 Bel = 10 decidels  $T_L = lo Lago T' de -10$ If the odd , log the = 0; the 10°  $\frac{T}{T} = 1 - 92$ 

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3

\$ IL= 1 dos

$$\frac{L_{0}}{L_{0}} = \frac{T}{10} ; \frac{T}{10} = (10)^{1/10} \\
 (\frac{T}{10}) = 1.26. \quad (0)^{1/10} \\
 (\frac{T}$$

1.26-1-0.26

Threshold of hearing	Intensity devel de
	0
Rustte of Leaves	10
Whisper	15-20
Averge Louse	40
Ordinary conversation	60-65
Motors sos heavy traffic	70-80
Roaring of him at 20 fe	ret 90
Themder	100-110
painful Sound	1202

Reverberation:

then a Sound pulse is produced is a half. He Sound wave travels towards all directions and are reflected back by the walls, floors, doors, windows, ceiling et o There are many reflections, before it becomes isaudible.

"The existence (50) probagation (or persistence of Sound is the hall even after the Source of Sound is stopped is called Reverserations."

(G)

Reverseration time

The five taken for the gound to fall below the minimum audibility measured from the instant when the Source stopped sounding. Satrier formula T. 0.767 V in wat man Zaas within m V- volume of Hall 1 - Surface area a - attomptions leefforcent of the materials kept house Factors affecting the Acoustics of Buildings

puning the sound promptilion, There is a possibility for causing interference between those waves which intern affects the originality of the sound produced.

1. anophinised reverberation the

R. Verylow con very high Condrons

2. Suppoper focusing of sound to a particular area which may cause interforence

9. schoes un Echelon effeils produced inside The buildings.

5. Resonance caused due to matching of sound waves.

6. Unwanted burd from outside on inside the building, so called roise may also effect the accurtion of buildings

# Tocuations

Accumulation of sound waves con direction of propagation of sound waves only in particular direction is known as focus, one this focus, the centromity of Sound distribution inside a hall withhold to equal. Superference

Two it nove sound waves may meet eachother dering its propagation is called interference. This is terference of sound will change the original guality of sound.

# Echoes & Echelon Effect.

In some halls, the walls of the halls will scatter the Sound waves rather than reflecting it, this may Create missance effect due to caloes

The echones are formed when the time interval between othe direct and selflected Sound waves are about 1/15th of a second. This effect occurs due to the reason that the reflected Sorend waves reaches the Aserva later Than the direct Sound.

If there is a signal separation of echoes of the original sound to the observer then the effect is called as Echelon effect.

Sound absoring materials

6

Resonance

Resonance occurs when a new sound note of frequency matches with Standard audio frequery. Some liver the ander panel, seeking of ander proton are Thrown into vibrations to produce new sounds, which sendly interference between original build and Greated sound. - Se can be anoided by providing proper vantichin and by adjusting the reventenction time - Air conditioning is Completely elimentity the seconomic Noise:

Noise is an anwanted sound produced due to beavy braffic outside the hall which leads to displeasing effect on the eer. Then are three types in noise i) Airborne noise ii) Structure borne noise iii) Structure borne noise iii) Inside noise

Aitsome noise

The noise which reaches the hall through open Windows, doors and ventilations are called as air some roise.

Structure bone noise:

The noise that reaches the hall through the
structures of the suilding are tained as structure
bome noise.
and that and about the products and seconds april
Inside notse:
The noise that are produced criste the halls
à trous ar énsite roise.
factors to sefollowed for good Acoustion of Building
() The teverseration the should have an optimum level.
is the sound must be evenly distributed to each and
every part of the building
(1) Those should not be any focurring of come I a
partialas area
displaced effects on the car
(iv) Each and every note of sound must be heard
Clearly and distinctly without any interference
12) echoes, echelon effect and resonance croside the
Fuildings Should be eliminated
() building should be a sound proof building
in Quality of sound to be a liter
Server to all allally
Equally .

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#### Ultrasonics

#### 1 . Define Ultrasonic waves?

The sound waves having frequencies above the human audible range are known as ultrasonic waves. i.e. Above 20KHz or 2000Hz.

2. Name the methods for the production of ultrasonic waves?

- 1. Mechanical generators or Galton Whistle method
- 2. Magnetostriction method
- 3. Piezo electric method

#### 3. Mention the properties of ultrasonic waves?

- 1. Ultrasonic waves have high sound frequency. i.e. > 20Khz.
- 2. It travels longer distance with no appreciable loss of energy.
- 3. Its velocity is constant for a homogeneous medium.
- 4. Like ordinary sound waves , ultrasonic waves get reflected, refracted and absorbed.

5. Ultrasonic waves produce intense heating effect when passed through a substance.

#### 4. What is magnetostriction effect?

When a rod of ferromagnetic materials like nickel, iron, cobalt etc, is placed in an alternating magnetic field parallel to its length, an alternate expansion and contraction are occur. This effect is known as magnetostriction effect.

#### 5. What is Piezo electric effect?

When a mechanical pressure is applied to one pair of opposite faces of certain crystals like quartz, tourmaline, Rochelle salt, etc, an equal and opposite electrical charges are developed on the other two faces of the crystal.

#### 6. What is Inverse Piezo electric effect?

When an electric field is applied to one pair of opposite faces of a quartz crystal, expansion or contraction is developed across the other pair of opposite faces of the crystal. This is called inverse piezo electric effect.

# 7.Define Cavitation?

When the ultrasonic waves pass through a liquid, they produce alternate regions of rarefaction and compression in the liquid.

A negative local pressure at the spot of rarefaction causes local boiling of the liquid accompanied by the bubble growth and collapse. This is known as cavitation.

8.Explain the phenomenon of magneto striction. How will you produce high frequency sound waves with its help?

When a rod of ferromagnetic materials like nickel, iron, cobalt etc, is placed in an alternating magnetic field parallel to its length, an alternate expansion and contraction are occur. This effect is known as magnetostriction effect.

#### Construction:

A ferromagnetic rod is clamped at the middle between two knife edges.

Coil  $L_1$  is wound on the right end of the rod. It is connected to a collector of

Coil  $L_2$  is wound on the left end of the rod. It is connected to base of the transistor. This coil is used as a feedback loop.

A variable capacitor is connected with coil L<sub>1</sub> parallel.

#### Working:

When the battery is switched on, The oscillator circuit  $L_1C$  (Tank circuit) Produces an alternating current .The frequency of  $L_1C$  is

$$f = \frac{1}{2\pi\sqrt{L_I}C}$$

This alternating current flows through the coil  $L_1$  and it produces an alternating magnetic field along the length of the rod. The rod begins to vibrate due to magnetostrictive effect.

The variable capacitor is adjusted to set the frequency of alternating current is equal to the natural frequency of the rod. Now the resonance condition occurs.



The rod vibrates with maximum amplitude. If the frequency of the alternating current lies in ultrasonic frequency range, then the rod produces ultrasonic waves from its both ends.

The natural frequency of vibration of the rod is

$$f_n = \frac{1}{2l} \sqrt{\frac{E}{\rho}}$$

Where L = Length of the rod.

E= young's modulus of the material of the rod

 $\rho$  = Density of the material of the rod

#### Condition for Resonance:

Frequency of the oscillator circuit = Frequency of the vibrating rod

$$F = \frac{I}{2\pi\sqrt{L_1C_1}} = \frac{1}{2l}\sqrt{\frac{E}{\rho}}$$

The changing magnetic flux in coil  $L_1$  induces an e.m.f in the coil  $L_2$ . This e.m.f is applied to the base of the transistor.

The high frequency oscillations in coil L<sub>1</sub> is sustained due to positive feedback.

Advantages:

• Low cost

- Simple design
- Large output

Disadvantage:

- Temperature dependent
- It has eddy current and hysteresis loss.

Describe Piezo- Electric effect method of producing ultrasonic waves?

#### 9.What are theCutting methods in Piezo Electric Crystals

The crystals which produce piezo-electric effect and converse Piezoelectric effect are termed as Piezo-electric crystal.

Examples: Quartz, Tourmaline, Rochelle Salts etc.

At typical example for a piezo-electric crystal (Quartz) is as shown in the figure 1.4.1. It has an hexagonal shape with pyramids attached at both ends. It consists of 3 axes . viz.,

(i) Optic Z axis, which joins the edges of the pyramid

- (ii) Electrical axis(X axis), which joins the corners of the hexagon and
- (iii) Mechanical axis (Y axis), which joins the center or sides of the hexagon as shown





X-cut and Y cut crystals

#### X - Cut crystal :

When the crystal is cut perpendicular to the X- axis, as shown in the figure 1.4.2, then it is called X – crystal.

Generally X- cut crystals are used to produce longitudinal ultrasonic waves.

#### Y-cut Crystal:

When the crystal is cut perpendicular to the Y –axis, as shown in the figure 1.4.3, then it is called Y –cut crystal.

Generally, Y –cut crystals produces transverse ultrasonic waves.

#### 10.Describe Piezo- Electric effect method of producing ultrasonic waves?

#### Principle:

This is based on the *Inverse piezoelectric effect.* When a quartz crystal is subjected to an alternating potential difference along the electric axis, the crystal is set into elastic vibrations along its mechanical axis. If the frequency of electric oscillations coincides with the natural frequency of the crystal, the vibrations will be of large amplitude. If the frequency of the electric field is in the ultrasonic frequency range, the crystal produces ultrasonic waves.



#### **Construction:**

The circuit diagram is shown in the figure 1.5 It is base tuned oscillator circuit. A slice of Quartz crystal is placed between the metal plates A and B so as to form a parallel plate capacitor with the crystal as the dielectric. This is coupled to the electronic oscillator through the primary coil  $L_3$  of the transformer.

Coils  $L_2$  and  $L_1$  of oscillator circuit are taken for the primary of the transformer. The collector coil  $L_2$  is inductively coupled to base coil  $L_1$ . The coil  $L_1$  and variable capacitor Cform the tank circuit of the oscillator.

#### Working:

When the battery is switched on, the oscillator produces high frequency oscillations. An oscillatory e.m.f is induced in the coil  $L_3$  due to **transformer** action. So the crystal is now under high frequency alternating voltage.

The capacitance of  $C_1$  is varied so that the frequency of oscillations produced is in resonance with the natural frequency of the crystal. Now the crystal vibrates with larger amplitude due to resonance. Thus high power ultrasonic waves are produced.

#### **Condition for Resonance:**

#### Frequency of the oscillator circuit = Frequency of the vibrating crystal

$$F = \frac{I}{2\pi\sqrt{L_1C_1}} = \frac{P}{2l}\sqrt{\frac{E}{\rho}}$$

Where 'l' is the length of the crystal

'E' is the Young's modulus of the rod

''  $\rho$ ' is the density of the material of the rod

'P' = 1, 2, 3 ...etc for fundamental, first overtone, second overtone etc respectively

#### Advantages:

- 1. Ultrasonic frequencies as high as 500 MHz can be generated.
- 2. The output power is very high. It is not affected by temperature humidity.
- 3. It is more efficient than the Magnetostriction oscillator.
- 4. The breadth of the resonance curve is very small. So we can get a stable and constant frequency of ultrasonic waves.

#### **Disadvantages:**

- 1. The cost of the quartz crystal is very high.
- 2. Cutting and shaping the crystal is quite complex.

# Sound Navigation and Ranging (SONAR)

# Principle:

It is based on the principle of Echo – Sounding. When the Ultrasonic waves are transmitted through water, it is reflected by the objects in the water and will produce an echo signal. The change in frequency of the echo signal, due to Doppler Effect helps us in determining the velocity and the direction of the object.



#### **Description:**

It consists of timing section which triggers the electric pulse from the pulse generator. This pulse generator is connected to the transducer so that ultrasonics can be produced. The transducer is further connected with the CRO for display. The timing section is also connected to the CRO display for reference of the timing at which the pulse is transmitted as shown in the block diagram.

# Working:

- > The transducer is mounted on the ship's hull without any air gap between them as shown.
- > The timing at which the pulse generated is recorded at the CRO for reference .
- Electrical pulse triggers the transducer which is kept in the hull of the ship to produce ultrasonic waves due to the principle of inverse piezo-electric effect.
- > These ultrasonic waves are transmitted through the water in sea.
- On striking the object the ultrasonic waves (*echo pulses*) are reflected in all directionsas shown in the figure.



# Determination of Ultrasonic Velocity in Liquid (Acoustical Grating Method)

# **Principle**:

When ultrasonic waves travel through a transparent liquid, due to alternate compression and rarefaction, longitudinal stationery waves are produced. If monochromatic light is passed through the liquid perpendicular to these waves, the liquid behaves as diffraction grating. Such a grating is known as **Acoustic Grating**. It is used to find wavelength ( $\lambda$ ) and velocity (v) of ultrasonic waves in the liquid.

# **Construction:**

- It consists of a glass tank, filled with the liquid.
- A piezo-electric (Quartz) is fixed at the bottom of the glass tank and is connected with piezoelectric oscillatory circuit as shown in the figure .
- An incandescent lamp is used as a monochromatic source (S) and a telescope arrangement is used to view the diffraction pattern.
- A collimator consisting of two lenses L<sub>1</sub> and L<sub>2</sub> is used to focus the light effectively in the glass tank.





#### Working

#### (i) When the piezo-electric crystal is kept at rest:

Initially the piezo-electric crystal is kept at rest and the monochromatic at light is switched ON. When the light is focused in the glass tank filled with the liquid, a single image, a vertical peak is observed in telescope. i.e., there is no diffraction.

#### (ii) When the piezo-electric crystal is set into vibrations:

Now the crystal is put into vibrations using piezo-electric oscillatory circuit. At Resonance, Ultrasonic waves are produced and are passed through the liquid. These Ultrasonic waves are reflected by the walls of the glass tank and form a stationery wave pattern with nodes and antinodes in the liquid. *At nodes the density of the liquid becomes more and at antinodes the density of the liquid becomes more and at antinodes the density of the liquid becomes as a diffracting element called acoustical grating element.* 

Now when the monochromatic light is passed the light gets diffracted and a diffraction pattern consisting of central maxima and principle maxima on either side is viewed through the telescope as shown in figure .



#### **Calculation of Ultrasonic Velocity**

The velocity of Ultrasonic waves can be determined using the condition.

 $2d\sin\theta = n\lambda \longrightarrow (1)$ 

Where, d is the distance between successive node or antinodes.

 $\boldsymbol{\theta}$  is the angle of diffraction

n is the order of the spectrum

 $\lambda_L$  is the wavelength of the monochromatic source of the light.

If  $\lambda_u = 2d$  (2)

Then, equation (1) becomes,

$$\lambda_u \sin \theta = n\lambda$$

Wavelength of Ultrasonic =  $\lambda_u = \frac{n\lambda}{\sin\theta}$  (3)

We know, Ultrasonic Velocity = Frequency of Ultrasonic × Wavelength of ultrasonic

	$v = \lambda \times v$		
Velocity of Ultrason	$ c v - v_u + v_u $	(4)	

Substituting equation (3) in (4), we get

Velocity of Ultrasonic wave $v = \frac{v_u n \lambda_1^2}{v_u n \lambda_2^2}$			
	$\sin \theta$		

Thus, this method is useful in measuring the wavelength and velocity of ultrasonic waves in liquids, and gases at various temperatures.

#### Ultrasonic Non- destructive Testing (NDT)

**Principle:** The basic principle behind the ultrasonic inspection is the transmission of the Ultrasound with the medium and the reflection or scattering at any surface or internal discontinuity in the medium due to the change in the acoustic impedance. The Discontinuity means the existence of the flaw or defect or cracks or hole in the material. The reflected or scattered sound waves are received and amplified and hence, the defects in the specimen are suitably characterized.



Block diagram of the Ultrasonic Flaw detector

#### **Principle:**

Whenever there is a change in the medium, then the Ultrasonic waves will be reflected. This is the principle used in Ultrasonic flaw detector. Thus, from the intensity of the reflected echoes, the flaws are detected without destroying the material and hence this method is known as a Non –Destructive method.

#### Working:

- The pulse generator generates high frequency waves and is applied to the Piezo-electric transducer and the same is recorded in the CRO.
- The piezo-electric crystals are resonated to produce Ultrasonic waves.
- These Ultrasonic waves are transmitted through the given specimen.
- These waves travel through the specimen and is reflected back by the other end.
- The reflected Ultrasonic are received by the transducer and is converted into electric signals. These reflected signals are amplified and is recorded in the CRO.
- If the reflected pulse is same as that of the transmitted pulse, then it indicates that there is no defect in the specimen.
- On the other hand, if there is any defect on the specimen like a small hole or pores, then the Ultrasonic will be reflected by the holes (i.e.) defects due to change in the medium.

- From the time delay between the transmitted and received pulses, the position of the hole can be found.
- From the height of the pulse received the depth of the hole can also be determined.

#### ULTRASONIC SCANNING METHODS- A, B AND C SCAN DISPLAYS

In the Ultrasonic scanning methods, the principle, construction and working is the same as that of the Ultrasonic flaw detector. Here, it is based on the position of the transducer and the output displayed in the CRO screen, we can classify the scanning methods into three types

- a. A-scan
- b. B-scan
- c. T-M scan or C-scan

All these three modes of scanning are obtained with respect to the pulses of Ultrasound transmitted into and received from the specimen. The three modes are explained below.

#### a. A-Scan or Amplitude mode display

- It is the most common display mode
- The received echo pulse amplitude is plotted as displacement along Y axis
- The travel time of the ultrasonic pulse (pulse transit time) is plotted as displacement along X axis.

The thickness (d) of the test piece can be calculated as,  $d = \frac{vt}{2}$ 

Where, t'-time interval between the initial (A) and backwall pulse (C)

v-velocity of the ultrasonic waves in the medium.

- Larger the thickness (d), greater is the time taken for the ultrasonic pulses to travel
- Therefore, from the time interval of the flaw pulse, the location of the flaw inside the specimen can be estimated.

The A-scan presentation displays the amount of received ultrasonic energy as a function of time.

- *IP*, Initial pulse generated by the transduceris represented by the signal
- A, thesound energy reflecting from surface
- BW, a signal from the back-wall

#### **B**, flaw - I (halfway between the frontand back surfaces of the sample)

**C,** flow - II



#### b. **B-Scan or Brightness Mode Scan**

In the B-scan, the time-of-flight (travel time) of the sound energy is displayed along the vertical and the linear position of the transducer is displayed along the horizontal axis.

- It gives two dimension display
- Here the transducer can be moved.
- As a result the echo's are displayed as in the figure
- Brightness & size of the dot intensity and strength of reflected echo pulse
- It provides information about internal structures



In the figure,

A indicates the initial pulse

B is the flaw pulse

C is due to back wall reflection

The depth of the flaw from the surface is a measure of pulse transit time

#### c. T.M Scan or Time – Motion Mode or C-Scan display

In a C-Scan,

- > The transducer probe is scanned over the surface of the test piece
- A display memory stores the echo amplitudes corresponding to various positions of the scan surface
- > The stored information are regenerated on CRT screen
  - > Any plane at a given depth can be imaged on the screen



- Mapping of defects in a 2D graphical representation from top view of the test surface is displayed
- The C-scan presentation provides a plan-type view of the location and size of test specimen features.
- > The plane of the image is parallel to the scan pattern of the transducer.
- C-scan presentations are produced with an automated data acquisition system, such as a computer controlled immersion scanning system.
- Typically, a data collection gate is established on the A-scan and the amplitude or the time-offlight of the signal is recorded at regular intervals as the transducer is scanned over the test piece.

- The relative signal amplitude or the time-of-flight is displayed as a shade of gray or a color for each of the positions where data was recorded.
- The C-scan presentation provides an image of the features that reflect and scatter the sound within and on the surfaces of the test piece.

#### Sonogram- Recording of movement of Heart

#### 1.11.1 Fetal Heart Movement

#### Principle:

It works under the principle of Doppler Effect i.e., there is an apparent change in the frequency between the incident sound waves on the fetus and the reflected sound waves from the fetus.

#### Description:

It consists of a Radio Frequency Oscillator (RFO), for producing 2 MHz of frequency and RFA (Radio Frequency Amplifier) to amplify the receiver signals as shown in the figure 1.11.1



#### Working:

The transducer is fixed over the mother's abdominal wall, with the help of a gel or oil. RFO is switched on to drive the pulses and hence the transducer produces Ultrasonic waves of 2 MHz. These Ultrasonic waves are made to be incident on the fetus.

The reflected Ultrasonic waves from the fetus are received by the transducer and are amplified by RFA. Both the incident and the received signals are mixed by the mixer and is filtered to distinguish the various types of sound and finally the Doppler shift or change in frequency is measured. The movement of the heart can be viewed visually by CRO or can be heard by the Loud Speaker, after necessary amplification by AF.

# **Ultrasonic Imaging System**



#### Principle of Working

- During the scanning of the body surface by Ultrasonic transducer, the Ultrasonic waves are transmitted into the patient's body.
- The echoes from the body are collected by the receiver circuit.
- Since some echoes come from the depth, they are weak; therefore, proper depth gain compensation is given by DGC circuit.
- Then these signals are converted into digital signals by an analog to digital converter and are stored in the memory of the Control Processing Unit (CPU) of a computer.
- Meanwhile, the control unit in the CPU receives the signals of transducer position and TV synchronous pulses. These signals generates X plate and Y plate address information's for the T.V monitor and is also stored in the memory of the CPU.
- The stored signals are processed and colour coded and is given to the digital to analog (D/A converter), which converts the digital signal into analog signal.
- Finally the mixing circuit mixes the analog signals and TV synchronous signals properly. The mixed signals are finally fed to the video section of the television monitor as shown in the figure
- The TV monitor produces the coloured Ultrasonic image of the internal part of the Body



Scanning Picture

## **UNIT III- THERMAL PHYSICS**

# PART - A

#### **1. Define heat Conduction.**

Conduction is the process of transmission of heat from one point to another through substance (or some medium) without the actual motion of the particles (atoms / molecules) of the substance.

#### 2. Define co-efficient of thermal conductivity and mention its unit.

- It is defined as the quantity of heat conducted per second normally across unit area of cross-section per unit temperature difference per unit length of the material.
- Its unit is watt / metre / Kelvin (Wm<sup>-1</sup> K<sup>-1</sup>)

# 3. What is basic principle behind Lee's disc method in determining thermal conductivity of bad conductor?

The given bad conductor is taken in the form of disc is placed in between the metal disc (Lee's disc) and steam chamber. The steam is passed through the steam chamber. Heat conducted through bad conductor per second is calculated. Amount of heat lost per second by disc is also calculated.

At steady state

 $\begin{pmatrix} Heat \ conducted \ through \ the \\ bad \ conductor \ per \ second \end{pmatrix} = \begin{pmatrix} Amount \ of \ heat \ lost \ per \ second \\ by \ the \ disc \end{pmatrix}$ 

From this, thermal conductivity of the bad conductor is calculated.

# 4. How are heat conduction and electrical conduction analogous to each

## other ?

	Heat conduction	Electrical conduction
1.	Heat is conducted from a point of higher temperature to a point of lower temperature.	Electricity is conducted from a point at higher potential to a point at lower potential.
2.	In metals, heat conduction is mainly due to free electrons.	In metals, electrical conduction is due to free electrons.
3.	The ability to conduct heat is measured by thermal conductivity.	The ability to conduct electricity is measured by electrical conductivity.

# 5. What are the characteristics of good and bad conductors ?

	Good conductors	Bad Conductors
1.	They have high electrical & thermal conductivity	They have very low electrical and thermal conductivity
2.	They can be easily heated or cooled.	They cannot be easily heated or cooled.
3.	Examples : Metals like iron, copper	<b>Examples :</b> Non metals like glass, wood.

# 6. What is thermal resistance?

The thermal resistance of a body is a measure of its opposition to the flow of heat through it.

# 7. Explain why the specimen used to determine thermal conductivity of a

# bad conductor should have a larger area and smaller thickness.

For a bad conductor with a small thickness and large area of cross - section, the amount of heat conducted increases (large), This will increase accuracy of the measurement.

## <u> PART - B</u>

#### 1) EXPLAIN FLOW OF HEAT THROUGH COMPOUND MEDIA.

#### Material bars in series

Let us consider a compound media of two different materials A and B with thermal conductivities  $K_1$  and  $K_2$  and thickness  $x_1$  and  $x_2$ .

The temperatures of the outer faces of A and B are  $\theta_1$  and  $\theta_2$ . The temperature of the surface in contact is  $\Theta$ . When the steady state is reached, the amount of heat flowing per second (Q) through every layer is same.



After the steady state is reached,

Amount of heat flowing through the material (A) per second

$$Q = \frac{K_1 A (\theta_1 - \theta)}{x_1} \qquad ----- (1)$$

Amount of heat flowing through the material (B) per Second

$$Q = \frac{K_2 A \left(\theta - \theta_2\right)}{x_2} - \dots - (2)$$

The amount of heat flowing through the materials A and B is equal in steady state conditions.

Hence, the eqns (1) & (2) are equal

$$\frac{K_1 A \left(\theta_1 - \theta\right)}{x_1} = \frac{K_2 A \left(\theta - \theta_2\right)}{x_2} \dots (3)$$

Rearranging the eqn (3), we have

$$K_1 A (\theta_1 - \theta) x_2 = K_2 A (\theta - \theta_2) x_1$$

$$K_1\theta_1x_2 \quad -K_1\mathbf{\theta}x_2 = K_2\mathbf{\theta}x_1 - K_2\theta_2x_1$$

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Rearranging,

$$K_{1}\theta_{1}x_{2} + K_{2}\theta_{2}x_{1} = K_{2}\theta x_{1} + K_{1}\theta x_{2}$$

$$K_{1}\theta_{1}x_{2} + K_{2}\theta_{2}x_{1} = \theta (K_{2}x_{1} + K_{1}x_{2})$$

$$\theta = \frac{K_{1}\theta_{1}x_{2} + K_{2}\theta_{2}x_{1}}{K_{2}x_{1} + K_{1}x_{2}} - \dots (4)$$

#### This is the expression for interface temperature of two composite slabs in series.

Substituting for  $\boldsymbol{\theta}$  in equation (1), We get

$$Q = \frac{K_1 A}{x_1} \left[ \theta_1 - \left( \frac{K_1 \theta_1 x_2 + K_2 \theta_2 x_1}{K_2 x_1 + K_1 x_2} \right) \right]$$
$$= \frac{K_1 A}{x_1} \left[ \frac{\left[ \theta_1 (K_2 x_1 + K_1 x_2) - (K_1 \theta_1 x_2 + K_2 \theta_2 x_1) \right]}{K_2 x_1 + K_1 x_2} \right]$$
$$= \frac{K_1 A}{x_1} \left[ \frac{\left[ (K_2 \theta_1 x_1 + K_1 \theta_1 x_2) - K_1 \theta_1 x_2 - K_2 \theta_2 x_1 \right]}{K_2 x_1 + K_1 x_2} \right]$$
$$= \frac{K_1 A}{x_1} \left[ \frac{\left[ (K_2 \theta_1 x_1) - K_2 \theta_2 x_1 \right]}{K_2 x_1 + K_1 x_2} \right]$$
$$= \frac{K_1 A K_2 x_1 (\theta_1 - \theta_2)}{x_1 [K_2 x_1 + K_1 x_2]}$$

$$= \frac{A(\theta_1 - \theta_2)}{\frac{K_2 x_1}{K_1 K_2} + \frac{K_1 x_2}{K_1 K_2}}$$

The amount of heat flowing per second through the compound wall of two materials.

Q = 
$$\frac{A(\theta_1 - \theta_2)}{\frac{x_1}{K_1} + \frac{x_2}{K_2}}$$
------(5)

This method can also be extended to composite slab with more than two slabs.

In general for any number of slabs, the amount of heat conducted per sec is given by

$$Q = \frac{A(\theta_1 - \theta_2)}{\Sigma(\frac{x}{K})} \qquad -----(6)$$

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#### **Material in Parallel**

Consider a composite media of two different materials A and B with thermal conductivities  $K_1$  and  $K_2$  and thicknesses  $x_1$  and  $x_2$ . They are arranged in parallel as shown in fig.



The faces of the material A and B are at temperature  $\theta_1$  and the other end faces of A and B are at temperature  $\theta_2$ . A<sub>1</sub> and A<sub>2</sub> are the area of cross - section of the materials.

Amount of heat flowing through the first material (A) in one second.

$$Q_1 = \frac{K_1 A_1 (\theta_1 - \theta_2)}{x_1} \dots (1)$$

Similarly

Amount of heat flowing through the second material (B) in one second.

$$Q_2 = \frac{K_2 A_2 (\theta_1 - \theta_2)}{x_2} - \dots - (2)$$

The total heat flowing through these materials per second is equal to the sum of  $Q_1$  and  $Q_2$ .

$$Q = Q_1 + Q_2$$
  
=  $\frac{K_1 A_1(\theta_1 - \theta_2)}{x_1} + \frac{K_2 A_2(\theta_1 - \theta_2)}{x_2}$ ----- (3)

Amount of heat flowing per second

$$Q = (\theta_1 - \theta_2) \left[ \frac{K_1 A_1}{x_1} + \frac{K_2 A_2}{x_2} \right] - \dots (4)$$

In general, the net amount of heat flowing per second parallel to the composite slabs is given by

$$\mathbf{Q} = (\boldsymbol{\theta}_1 - \boldsymbol{\theta}_2) \sum \frac{KA}{x} \dots (5)$$

#### 2) EXPLAINFORBES METHOD - THEORY AND EXPERIMENT.

This is one of the earliest method to find the absolute thermal conductivity of metals. **Theory of the Experiment** 

Consider a long rod. This rod is heated at one end and a steady state is reached after some time.

Amount of heat flowing per second across the cross-section A at the point B

$$= \mathrm{KA}\left(\frac{d\theta}{dt}\right)_B$$

Consider an element of thickness dx of the rod. Mass of the element =  $(Adx) \rho$ 

Where  $\rho$  - density of the rod [ Mass = Volume x density]

Heat lost by the element per second

= Mass x Specific heat capacity x rate of fall of temperature

$$= (Adx)\rho \times S \times \frac{d\theta}{dt} - \dots (2)$$

Total heat lost by the portion of the rod between section B and the end C

=

$$= \int_{C}^{B} (Adx) \rho S \frac{d\theta}{dt} - \dots (3)$$

Amount of heat flowing per second across the cross Section at the point B. Heat lost by radiation by radiation by the rod. beyond the section B.

KA 
$$\left(\frac{d\theta}{dx}\right)_{\rm B} = \int_{C}^{B} (Adx) \rho \, \mathrm{S} \, \frac{d\theta}{dt}$$
----- (4)

$$\mathbf{K} = \frac{\rho \, \mathbf{S} \, \int_{C}^{B} \frac{d\theta}{dt} \, \mathrm{dx}}{\left(\frac{d\theta}{dt}\right)_{B}} \quad \dots \dots \quad (5)$$

#### **Experiment consists of two parts**

- 1. Static experiment to find  $\left(\frac{d\theta}{dt}\right)_{R}$
- 2. Dynamic experiment to find  $\frac{d\theta}{dt}$  and  $\int_C^B \frac{d\theta}{dt} dx$
# **1. Static Experiment**

The specimen metal is taken in the form of a long rod. One end of this rod is heated by a steam chamber. The rod has a series of holes into which thermometers are fitted. These thermometers record temperatures at different points along the rod.



When the steady state is reached, the temperature  $(\theta)$  shown by the thermometers of the rod and their respective distances (x) from the hot end are noted.

A graph is drawn between the temperature  $(\mathbf{\theta})$  and the

distance (x) from the hot end.



The Value of  $\left(\frac{d\theta}{dt}\right)_B$  is obtained by drawing a tangent to the curve at a point B.

If this tangent makes an angle  $\alpha$  with the x axis, then from the graph.

$$\left(\frac{d\theta}{dt}\right)_B = \frac{AB}{BC} = \tan \alpha$$

# 2. Dynamic experiment

A piece of the original rod is heated to the same temperature as that of the hot end in the static experiment. The heated piece of the rod is suspended in air.

Now, it is allowed to cool. Its temperature is noted at regular intervals of time by a thermometer place in a hole at the centre.

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A graph is drawn between temperature  $(\mathbf{\theta})$  and time (t)



From this graph, the value of  $\frac{d\theta}{dt}$  for various values of  $\theta$  are determined by drawing tangents at various points of the cooling curve.

Even the graph between temperature  $\Theta$  and the distances of hot end x for various values of temperature  $\Theta$  are obtained. Now, third graph is drawn between  $\frac{d\theta}{dt}$  and the corresponding values of x.



The curve is extended to meet the x - axis. Corresponding to the point B, a point is located on the curve.

The area bounded by the curve, x - axis and the ordinate passing through B is  $\int_C^B \frac{d\theta}{dt} dx$ 

The area of the shaded portion is determined.

We know that

$$\mathbf{K} = \frac{\rho \, \mathrm{S} \, \int_{C}^{B} \frac{d\theta}{dt} \, \mathrm{dx}}{\left(\frac{d\theta}{dt}\right)_{B}}$$

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substituting the values in the above equation, we have

# $\mathbf{K} = \frac{\rho \, S \, x \, (Area \, of \, the \, shaded \, portion)}{\rho \, S \, x \, (Area \, of \, the \, shaded \, portion)}$

#### tan α

Hence, K is determined

#### Merits

It is one of the earliest method to determine the absolute thermal conductivity of the material.

# **Demerits**

- It is tedious method and requires a lot of time for the completion of the experiment and drawing the three graphs.
- The specific heat capacity of the material of the rod does not remain constant at different temperatures as assumed.
- > The distribution of heat is not uniform along the bar in the two experiments. Therefore, this experiment is not accurate.

# **3) EXPLAIN LEE'S DISC METHOD - THEORY AND EXPERIMENT**

The thermal conductivity of bad conductors like glass, ebonite or card board is determined by this method.

#### Description

- The apparatus consists of a circular metal disc or slab (C) (Lee's disc) of radius r and thickness H suspended by the strings from a stand.
- The given bad conductor (such as glass, ebonite) is taken in the form of a disc (D). This bad conductor has the same diameter as that of the slab is placed on the bad conductor. There are holes in steam chamber and slab into which thermometers T<sub>1</sub> and T<sub>2</sub> are inserted to record the respective temperatures.



# Working

Steam is passed into the steam chamber until the temperatures in the chamber and the slab are steady. When thermometers  $T_1$  and  $T_2$  show steady temperatures, their readings  $\theta_1$  and  $\theta_2$  respectively are noted. The radius (r) and thickness (d) of the disc D are also measured.

# **Observation and calculation**

Thickness of the bad conductor	-	d
Radius of the bad conductor and metal disc	-	r
Mass of the slab (Lee's disc)	-	М
Thickness of the metal disc	-	h
Steady temperature in the steam chamber	-	$\theta_1$
Steady temperature in the slab	-	$\theta_2$
Thermal conductivity of the bad conductor	-	K
Rate of cooling of the slab at $\Theta_2$	-	R
Specific heat capacity of the slab	-	S
Area of the cross section $A = \pi r^2$		

Amount of the heat conducted through the disc D per second

$$Q = \frac{KA(\theta_1 - \theta_2)}{d} = \frac{K\pi r^2}{d} (\theta_1 - \theta_2)$$

- At this state all the heat conducted through the bad conductor is completely radiated by the bottom flat surface and the curved surface of the slab C.
- $\blacktriangleright$  Amount of heat lost per second by the slab C.

Q = Mass x Specific heat capacity x Rate of cooling

$$Q = MSR$$

At steady state,

Heat conducted through the	=	Heat lost per second
bad conductor per second		by the slab C

Hence, equations (1) and (2) are equal

$$\frac{K\pi r^2}{d}(\theta_1 - \theta_2) = \text{MSR}$$

$$\mathbf{K} = \frac{MSRd}{\pi r^2(\theta_1 - \theta_2)}$$

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# (ii) Determination of rate of cooling R.

- > The bad conductor is removed and the steam chamber is placed directly on the slab. The slab is heated to a temperature about 5 °C higher than $\theta_2$ . The steam chamber is removed and the slab alone is allowed to cool.
- > As the slab cools, the temperatures of the slab are noted at regular intervals of time (0.5 minute) until the temperature of the slab falls to about 5 °C below $\theta_2$ .

The temperature - time graph is drawn and the rate of cooling  $\frac{d\theta}{dt}$  at the steady temperature  $\theta_2$  is determined.



- During the first part of the experiment, before the removal of bad conductor and steam chamber, the top surface of the slab is covered surface area of the slab is covered by the bad conductor.
- Radiation is taking place only from the bottom surface area and curved surface area of the slab.

Total area = 
$$\pi r^2 + 2\pi rh = \pi r (r+2h)$$

In the second part of the experiment, heat is radiated from top surface area, bottom surface area and curved sides. i.e., over entire surface area.

 $\pi r^2 + \pi r^2 + 2\pi rh = 2\pi r^2 + 2\pi rh = 2\pi r (r + h)$ 

As the rate of cooling is directly proportional to the surfaces that are exposed (other condition being equal).

$$\frac{R}{\frac{d\theta}{dt}} = \frac{\pi r (r+2h)}{2\pi r (r+h)} = \frac{r+2h}{2(r+h)} = \frac{r+2h}{(2r+2h)}$$
$$R = \frac{r+2h}{(2r+2h)} \left(\frac{d\theta}{dt}\right)$$

Substituting for R in equation (3), We have

$$\mathbf{K} = \frac{MSd\left(\frac{d\theta}{dt}\right)}{\pi r^2(\theta_1 - \theta_2)} \frac{r+2h}{(2r+2h)}$$

Thus thermal conductivity of the bad conductor is determined.

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# 4) EXPLAIN BIMETALLIC STIRPS

# Definition

A bimetallic strip means a strip made of two metals of different expansions coefficients joined together .It is like compound bar.

# Principle

It operates on the principle that different metals have different coefficients of expansion.



# **Description and working**

- Two strips of brass and iron of equal lengths are joined together to form a bimetallic strip.
- > This bimetallic strip is straight at room temperature.
- Now, it is heated by using a burner. On heating, the metallic strip bends to form a curve in such a way that brass remains on the outside of the curve.
- This means that brass strip has become longer than the iron strip after heating, that is ,brass expands more than iron for the same rise in temperature.
- It is obvious that a bimetallic strip bends due to the unequal expansion rate of the two metals.
- In fact on heating, of the bimetallic strip bends towards iron side. If ,however, the bimetallic strip shown in fig.is cooled in freezing mixture, then it bends the other way showing that brass contracts more than iron.

# **Applications of bimetallic strips**

They are used as thermo-switches in automatic electrical heating and cooling appliances like thermostats, electric ovens, electric irons, fire alarms, and bimetallic thermo meters. A thermoswitch is a switch which works by the action of heat.

# **Quantum Physics**

# Formula

S.No	Description	Formula
1.	Stefan- Boltzmann's law	E $\alpha$ T <sup>4</sup> (or) E = $\sigma$ T <sup>4</sup> Where $\sigma$ = 5.67X10 <sup>-8</sup> W/m <sup>2</sup> k <sup>4</sup>
2.	Rayleigh- Jean's law	$E = 8\pi kT/\lambda^4$
3.	Wien's displacement law	$\lambda_m T = cons \tan t$ $\lambda_m \propto \frac{1}{T}$
4.	Wien's radiation law	$E_{\lambda} = \frac{8\pi hc}{\lambda^5} \frac{1}{e^{-hc/\lambda kT}}$ $E_{\lambda} = C_1 \lambda^{-5} e^{-C_2/\lambda T}$
5.	Planck's law of radiation	$E_{\lambda} = 8\pi hc/(\lambda^5 e^{h\nu/kt} - 1)$
6.	de- Broglie wave equation	$\lambda = h/p$ ; $\lambda = h/mv$
7.	de- Broglie wavelength in terms of energy	$\lambda = \frac{h}{\sqrt{2mE}}$
8.	de- Broglie wavelength associated with electrons	$\lambda = \frac{h}{\sqrt{2meV}}$
9.	Compton wavelength or Compton Shift	$d\lambda = \frac{h}{m_0 c} (1 - \cos \theta)$
10.	The total wave function	$\Psi = \psi e^{-i\omega t}$
11.	Schrodinger's time independent wave equation	$\nabla^{2}\psi + \frac{8\pi^{2}m}{\hbar^{2}}(E - V)\psi = 0$ or $\nabla^{2}\psi + \frac{2m}{\hbar^{2}}(E - V)\psi = 0$

12.	Schrodinger's time dependent wave equation	$(-\frac{\hbar^2}{2m}\nabla^2 + V)\psi = i\hbar\frac{\partial\psi}{\partial t}$ $H\psi = E\psi$
13	Energy of a particle in one dimensional box	$E_n = \frac{n^2 h^2}{8ma^2}$
14.	Wave function of a particle in one dimensional box	$\psi_n(x) = A \sin \frac{n\pi x}{a}$
15.	The normalised eigen function of a particle	$\psi_n = \sqrt{\frac{2}{a}} \sin \frac{n\pi x}{a}$

1 2

# Part- A

# 1. Mention some important applications of quantum physics?

- ▶ It is used to explain the concept of photo electric effect.
- > Specific heat of solids at low temperature is explained successfully.
- > The atomic structure and the origin of spectral lines are explained by Bohr based on quantum concepts.
- ➤ X-rays scattering is explained by Compton based on quantum ideas.
- Energy distribution in black body radiation is explained.

# 2. What is a Black body?

A body which absorbs and emits all the frequency of radiation fall on it, it is called a perfect black body.

Characteristics:

- > There is no perfect black body in practical.
- > We can make a black body artificially by painting the black over the surface.
- ➢ It is a perfect absorber and radiator.

#### 3. State Stefan- Boltzmann's law?

The total power per unit surface area radiated by a black body is directly proportional to the temperature.

E  $\alpha$  T<sup>4</sup> (or) E =  $\sigma$ T<sup>4</sup> , Where  $\sigma$  = 5.67X10<sup>-8</sup>W/m<sup>2</sup>k<sup>4</sup>

#### 4. State wein's law of energy distribution?

The product of emitted wavelength at maximum energy  $(\lambda_m)$  and absolute temperature (T) is constant.

$$\lambda_{\rm m} T = 2.89 {\rm X} 10^{-3} {\rm mK}$$

This law also states that the maximum energy radiated is directly proportional to the fifth power of temperature.  $E_{max} = T^5$ 

The energy density of emitted radiation  $E = Av^3 e^{-\beta v/T}$ 

This law holds good only for higher frequencies.

#### 5. State Rayleigh- Jean's law?

The energy distribution is directly proportional to absolute temperature and inversely proportional to the wavelength of radiation.

$$E = 8\pi kT/\lambda^5$$

Where  $k = 1.38 \times 10^{-23} \text{JK}^{-1}$  is Boltzmann's constant.

This law holds good only for Lower frequencies.

#### 6. State Planck's hypothesis.

- The radiation energy emitted by Black body is in the form of discrete packets or quanta called photons.
- > If the temperature of body increases, the emitted radiation frequency also increases.
- > The emitted radiation possess energy hv and momentum  $h/\lambda$ .

#### 7. State Planck's law of radiation?

The energy emitted in the form of packets or quanta called photons is given by

E = nhv.

Where n = 1,2,3 etc.

In black body radiation total energy of photons within the wavelength range  $\lambda$  and  $\lambda$ +d  $\lambda$  is given by

E<sub>$$\lambda$$</sub> = 8 $\pi$ hc/( $\lambda$ <sup>5</sup>e<sup>hv/kt</sup>-1)

#### 8. Define Compton effect.

When a photon of energy hv colloids with a substance , the scattering beam consists of two components.

One has the same frequency or wavelength as the incident ray.

Other has low frequency or high wavelength than the incident ray.

This effect is called as Compton effect. The change in wavelength is called Compton shift.

# 9. What are matter waves or De-broglie waves?

The waves associated with the matter particles (molecule, atom, proton, neutron, electron) are called matter waves or de Broglie waves.

# 10. What is de- Broglie wave equation?

A photon of frequency v has the momentum P = hv/c

$$\nu=c/\lambda \quad ; P=h/\lambda$$

W.k.t  $\lambda = h/P$ ;  $\lambda = h/mv$ 

If  $E_k$  is the k.E of the material particle,  $p = \sqrt{2mE_k}$ 

If a charged particle carrying charge q is accelerated through a potential difference V volts then K.E  $\ E_k = qv$ 

 $\lambda = h/\sqrt{2mqV}$ 

# **11. State the properties of matter waves?**

If mass of the particle is smaller, the wavelength associated it is longer.

If velocity of the particle is smaller, the wavelength associated is longer.

Matter waves are electromagnetic wave.

Velocity of matter wave is not constant.

# 12.What is physical significance of a wave function?

As the wave function  $\Psi$  is a complex quantity, it can be used to measure the variation of matter wave. It does not have direct physical meaning.

It is used to identify the energy states of a particle in an atomic structure.

 $\Psi\Psi^*$  or  $|\Psi|^2$  is the probability density function.  $\Psi\Psi^*dx dy dz$  gives the probability of finding the electron in the region of space between x and x +dx, y+dy and z+dz.

$$a_{a}\int^{a}\Psi\Psi^{*}dx dy dz = 1$$

# 13. What is the principle of travelling electron microscope?

When the high energy accelerated electrons are focussed on a sample, they can pass through the sample and image in the screen either by transmitted beam or diffracted beams. This gives the three dimensional image of the sample.

# 14. Define eigen value and eigen function?

Eigen value is defined as energy of the particle and is denoted by letter  $E_n$ .

Eigen function is defined as the wave function of the particle and is denoted by the letter  $\Psi_n$ .

# **15. Define degeneracy?**

The combinations of quantum numbers have same eigen values but different eigen functions. This kind of states are called degenerate state. if both the eigen function and eigen value is same then it is called non-degenerate state.

# Part- B

# **1.Derive planck's law for black body radiation and hence deduce wien's law and Rayleigh jeans law.**

Let us consider N no.of oscillators. E<sub>Tot</sub> is Total energy.

The average energy of an oscillator

Where  $N_0, N_1, N_2, N_3, \dots, N_r \rightarrow Oscillators$ 

0,1E,2E,3E,4E,5E,..... rE  $\rightarrow$  Corresponding energy of oscillator.

Total no.of oscillators  $N = N_0 + N_1 + N_2 + N_3 + \dots + N_r$ 

Total energy of oscillators E<sub>Tot</sub>= 0N<sub>0</sub>+ 1EN<sub>1</sub>+2EN<sub>2</sub>+3EN<sub>3</sub>+.....+rEN<sub>r</sub>

According to Maxwell Boltzmann distribution function,

The no.of oscillator having energy rE,

 $N_r = N_0 e^{-rE / Kt}$ .....(2)

Where k is called Boltzmann constant.

For 
$$r = 0$$
;  $N_0 = N_0 e^0$ 

For $r = 1$ ;	$N_1 = N_0 e^{\text{-}E/KT}$
For $r = 2$ ;	$N_2 = N_0 e^{-2E/KT}$
For $r = 3$ ;	$N_3 = N_0 e^{-3E/KT}$
For $\mathbf{r} = \mathbf{r}$ ;	$N_r \!= N_0 e^{\text{-}rE/KT}$

Therefore  $N = N_0 e^0 + N_0 e^{-E/KT} + N_0 e^{-2E/KT} + N_0 e^{-3E/KT} + \dots + N_0 e^{-rE/KT}$ 

Or

$$N = N_0 \left[ 1 + e^{-E/KT} + e^{-2E/KT} + e^{-3E/KT} + \dots + e^{-rE/KT} \right]$$

W.K.T 
$$1+x+x^2+x^3+... = 1/1-x$$

The total no.of oscillators  $N = N_0 [1/1 - e^{-rE/Kt}]$ .....(3)

By substituting the values of  $N_0, N_1, N_2, N_3, \dots, N_r$ , the total energy can be written as  $E_{tot} = 0$  $N_0 e^0 + E N_0 e^{-E/KT} + 2E N_0 e^{-2E/KT} + 3E N_0 e^{-3E/KT} + \dots + rE N_0 e^{-rE/KT}$ 

$$E_{tot} = N_0 [0 + Ee^{-E/KT} + 2Ee^{-2E/KT} + 3Ee^{-3E/KT} + \dots + rEe^{-rE/KT}]$$

$$E_{tot} = N_0 Ee^{-E/KT} [0 + 1 + e^{-E/KT} + 3e^{-2E/KT} + \dots + re^{-(r-1)E/KT}]$$
W.K.T
$$1 + 2x + 3x^2 + 4x^3 + \dots + rx^{r-1} = 1/(1-x)^2$$

Total energy of oscillators

 $E_{tot} = N_0 E e^{-E/KT} [ 1/(1-e^{-E/KT})^2].....(4)$ 

Substitute the values of (4) in (1),

$$\overline{E} = \frac{E_{TOT}}{N} = \frac{N_0 E e^{-E/KT}}{N_0 [\frac{1}{(1 - e^{-E/KT})}]} \left[ \frac{1}{(1 - e^{-E/KT})^2} \right]$$
$$\overline{E} = \frac{E e^{-E/KT}}{\frac{(1 - e^{-E/KT})}{e^{-E/KT}}}$$
$$\overline{E} = \frac{E}{\frac{1 - e^{-E/KT}}{e^{-E/KT}}}$$
$$\overline{E} = \frac{E}{1}$$

$$\overline{E} = \frac{E}{\frac{e^{E/KT} - 1}{e^{hv/KT} - 1}}$$

$$\overline{E} = \frac{hv}{e^{hv/KT} - 1}$$
(5)

The no.of oscillators per unit volume within the range of frequency v+dv,

$$N = \frac{8\Pi v^2}{c^3} dv \dots (6)$$

The energy density = No.of oscillators per unit volume x Average energy of an oscillator

$$E_v dv = N E$$

$$E_{v} = \frac{8\Pi h v^{3}}{c^{3}} \frac{1}{e^{hv/KT} - 1} \qquad .....(8)$$

w.k.t 
$$\mathbf{v} = \mathbf{c}/\lambda$$
 or  $\mathbf{dv} = \frac{-c}{\lambda^2} d\lambda$   
 $|dv| = \left| \left[ \frac{-c}{\lambda^2} \right] d\lambda \right| = \left[ \frac{c}{\lambda^2} \right] d\lambda$   
 $E_{\lambda} = \frac{8\Pi hc}{\lambda^5} \left[ \frac{1}{e^{hc/\lambda kT} - 1} \right] \dots (9)$ 

This law holds good for all the experimental results.

# 2.Define Compton scattering? Derive an expression for the Compton wavelength of the scattered photon?

When a photon of energy hv colloids with a substance, the scattering beam consists of two components.

One has the same frequency or wavelength as the incident ray.

Other has low frequency or high wavelength than the incident ray.

This effect is called as Compton effect. The change in wavelength is called Compton shift.



The electron of atom gains energy due photon collision. Then it moves with the velocity v at an angle  $\theta$  to x axis i.e recoil velocity.

Total energy before collision

Energy of incident photon = hv

Energy of an electron at rest  $= m_0 c^2$ 

 $C \rightarrow Velocity of light$ 

**EP/Quantum Physics** 

Total energy before coliision =  $hv + m_0c^2$ 

Total energy after collision

Energy of scattered photon = hv'

Energy of recoiled electron  $= mc^2$ 

Total energy after collision =  $hv' + mc^2$ 

According to conservation law of energy,

Total energy before collision = Total energy after collision

 $hv + m_0 c^2 = hv' + mc^2$ ....(1)

Total momentum along x axis before collision

Momentum of photon = hv / c

Momentum of electron = 0

Total momentum along x axis before collision  $= \frac{hv}{c} + 0 = \frac{hv}{c}$ 

Total momentum along x axis after collision

Momentum of scattered photon 
$$=\frac{hv'}{c}\cos\phi$$

Momentum of recoiled electron =  $mv \cos\theta$ 

Total momentum along x axis = 
$$\frac{hv'}{c}\cos\phi + mv\cos\theta$$

According to conservation law of momentum in along axis,

Total momentum before collision = Total momentum after collision

Total momentum along y axis before collision

Momentum of photon = 0

Momentum of electron = 0

Total momentum along y axis before collision = 0

Total momentum along y axis after collision

Momentum of scattered photon = 
$$\frac{hv'}{c}\sin\phi$$

Momentum of recoiled electron =  $-mvsin\theta$  (-ve sign indicates -ve y direction)

Total momentum along y axis after collision =  $\frac{hv'}{c}\sin\phi$  - mvsin $\theta$ 

According to conservation law of momentum,

Momentum before collision = Momentum after collision

$$0 = \frac{hv'}{c}\sin\phi - mv\sin\theta$$
$$\frac{hv'\sin\phi - mvc\sin\theta}{dt} = 0$$

hv'  $\sin \varphi - mv \sin \theta = 0$  or  $mv \sin \theta = hv' \sin \phi$ .....(3)

Squarring equ (2) & (3) and adding,

$$(mvccos\theta)^2 + (mvcsin\theta)^2 = h^2(v-v'cos\varphi)^2 + (hv'sin\varphi)^2$$

$$\underline{L.H.S} \qquad m^2 v^2 c^2 \cos^2\theta + m^2 v^2 c^2 \sin^2\theta = m^2 v^2 c^2 (\sin^2\theta + \cos^2\theta) = m^2 v^2 c^2$$

$$\underline{R.H.S} \qquad h^2 (v^2 - 2vv' \cos\varphi + v'^2 \cos^2\varphi) + h^2 v'^2 \sin^2\varphi$$

$$h^2 (v^2 - 2vv' \cos\varphi + v'^2 \cos^2\varphi + v'^2 \sin^2\varphi)$$

$$h^2 (v^2 - 2vv' \cos\varphi + v'^2 (\sin^2\varphi + \cos^2\varphi))$$

 $h^2(v^2-2vv'\cos\varphi+v'^2)$ 

 $(:: \sin^2 \varphi + \cos^2 \varphi = 1)$ 

:. 
$$m^2 v^2 c^2 = h^2 (v^2 - 2vv' \cos \varphi + v'^2)$$
 .....(4)

From equ (1), 
$$mc^2 = h(v-v')+m_0c^2....(5)$$

Squaring equ (5) on both sides,  $m^2c^4 = (h(v-v')+m_0c^2)^2$ 

$$m^{2}c^{4} = h^{2}(v^{2}-2vv'+v'^{2})+2h(v-v')m_{0}c^{2}+m_{0}^{2}c^{4}....(6)$$

Subtracting equ (4) from (6),

$$m^{2}c^{4}-m^{2}v^{2}c^{2} = h^{2}(v^{2}-2vv'+v'^{2})+2h(v-v')m_{0}c^{2}+m_{0}^{2}c^{4} - h^{2}(v^{2}-2vv'\cos\varphi+v'^{2})$$

$$m^{2}c^{2}(c^{2}-v^{2}) = -2h^{2}vv'+2h^{2}vv'\cos\varphi+2h(v-v')m_{0}c^{2}+m_{0}^{2}c^{4}$$
$$m^{2}c^{2}(c^{2}-v^{2}) = -2h^{2}vv'+2h^{2}vv'\cos\varphi+2h(v-v')m_{0}c^{2}+m_{0}^{2}c^{4}$$
$$m^{2}c^{2}(c^{2}-v^{2}) = -2h^{2}vv'(1-\cos\varphi)+2h(v-v')m_{0}c^{2}+m_{0}^{2}c^{4}.....(7)$$

The variation of mass with velocity from Special theory relativity,

Squaring equ (7) on both sides,

$$m^{2} = \frac{m_{0}^{2}}{1 - \frac{v^{2}}{c^{2}}} = \frac{m_{0}^{2}}{\frac{c^{2} - v^{2}}{c^{2}}} = \frac{m_{0}^{2}c^{2}}{c^{2} - v^{2}}$$
$$m^{2}(c^{2} - v^{2}) = m_{0}^{2}c^{2}$$

Multiplying  $c^2$  on both sides,  $m^2c^2(c^2-v^2)=m_0{}^2c^4$ .....(9)

Substituting equ (9) in (7)  $m_0^2 c^4 = -2h^2 v v'(1-cos\phi)+2h(v-v')m_0 c^2+m_0^2 c^4$ 

$$2h(v-v')m_0c^2 = 2h^2vv'(1-\cos\varphi) \quad \text{or}$$
$$\frac{v-v'}{vv'} = \frac{h}{m_0c^2}(1-\cos\varphi)$$
$$\frac{v}{vv'} \quad \frac{v'}{vv'} = \frac{h}{m_0c^2}(1-\cos\varphi)$$

$$\frac{1}{\boldsymbol{\nu}'} - \frac{1}{\boldsymbol{\nu}} = \frac{\boldsymbol{h}}{\boldsymbol{m}_0 \boldsymbol{c}^2} (1 \quad \cos \varphi)$$

Multiplied by c on both sides of above equ

$$d\lambda = \frac{h}{m_0 c} (1 - \cos \varphi)$$

Note:

The change in wavelength is due to angle of scattering.

 $d\lambda$  is independent of wavelength of incident radiation and nature of the substance.

Case: 1 When  $\theta = 0$ ,  $\cos \theta = 1$  and hence  $d\lambda = 0$ 

Case:2 When  $\theta = 90$ ,  $\cos\theta = 0$  and hence  $d\lambda = h/m_0c = 0.0243A^0$ 

Case3: When  $\theta = 180$ ,  $\cos\theta = -1$  and hence  $d\lambda = h/2m_0c = 0.0485A^0$ 

3.Describe the experimental verification of Compton scattering?





X-ray is allowed to fall on a scattering element.

The scattered ray is captured by a Bragg spectrometer.

The wave length of scattered ray is measured from every angle.

There exists a line of longer wave length, in addition to the incident wavelength.

The difference between the two wavelengths is known as Compton shift.

Thus the Compton effect is proved experimentally. It states that the particle nature of radiation also.

Compton shift is the function of scattered angle. i.e shift increases for the increase of scattered angle of photon.

#### 4. Derive the time independent Schrodinger equation for 3 dimensional motion.

Consider a wave pocket . x,y,z be the 3 co- ordinates.  $\Psi$  is the displacement of wave at any time t.



The classical differential equation of a wave motion,

Here v = wave velocity.

$$\nabla^2 \psi = \frac{1}{v^2} \frac{\partial^2 \psi}{\partial t^2}$$
 .....(2)

$$abla^{2} = rac{\partial^{2}\psi}{\partial x^{2}} + rac{\partial^{2}\psi}{\partial y^{2}} + rac{\partial^{2}\psi}{\partial z^{2}}$$

Where  $\nabla$  is laplacian operator.

The solution of equ

 $\psi(x, y, z) = \psi_0(x, y, z)e^{-i\omega t}$ ....(3)

 $\psi_0(x, y, z)$  is a function of x,y,z.

By differentiating,  $\frac{\partial \psi}{\partial t} = -i\omega \psi_0 e^{-i\omega t}$  and

$$\frac{\partial^{2}\psi}{\partial t^{2}} = i^{2}\omega^{2}\psi_{o}e^{-i\omega t}$$
$$\frac{\partial^{2}\psi}{\partial t^{2}} = -\omega^{2}\psi$$
.....(4)

$$\nabla^{2} \psi = -\frac{\omega^{2}}{v^{2}} \psi$$
$$\nabla^{2} \psi + \frac{\omega^{2}}{v^{2}} \psi = 0$$
.....(5)

But angular frequency  $\omega = 2\pi v = 2\pi \left( \left( \frac{v}{\lambda} \right) \right)$ 

w.k.t the De-broglie 
$$\lambda = \frac{h}{mv}$$
  
 $\nabla^2 \psi + \frac{4\Pi^2}{\frac{h^2}{m^2 v^2}} \psi = 0$ 

$$\nabla^2 \psi + \frac{1}{h^2} \psi = 0$$

 $\nabla^2 \psi + \frac{m^2 v^2}{\hbar^2} \psi = 0$ 

E (Total energy of the particle) = (Potential energy) V + Kinetic energy  $(\frac{1}{2} \text{ mv}^2)$ 

.....(8)

$$E - V = \frac{1}{2} mv^2$$
$$mv^2 = 2(E-V)$$

multiplying by m on both sides  $m^2v^2 = 2m(E-V)$ Substituting equ (8) in (9) we get ,

$$abla^2 \psi + rac{2m(E-V)}{\hbar^2}\psi = 0$$
 .....(9)

As there is no term to define time, it is called time independent equation.

#### 5. Derive the time dependent Schrodinger equation for 3 dimensional motion.

This equation is derived from Schrodinger time independent equation.

The solution of classical diff equation of wave motion

 $\psi(x, y, z) = \psi_0(x, y, z)e^{-i\omega t}$ ....(1)

By differentiating w.r.t 't' time,  $\frac{\partial \psi}{\partial t} = -i\omega \psi_0 e^{-i\omega t}$ 

$$\frac{\partial \psi}{\partial t} = -i(2\Pi v)\psi_0 e^{-i\omega t} \qquad \text{here } \omega = 2\pi v$$

$$\frac{\partial \psi}{\partial t} = -i2\Pi v\psi$$

$$\frac{\partial \psi}{\partial t} = -i2\Pi \frac{E}{h}\psi \qquad \because E = hv$$

$$\frac{\partial \psi}{\partial t} = -i\frac{E}{\frac{h}{2\Pi}}\psi \qquad \text{or} \qquad \frac{\partial \psi}{\partial t} = -i\frac{E}{h}\psi$$

Multiplying i on both sides,  $i \frac{\partial \psi}{\partial t} = -i^2 \frac{E}{\hbar} \psi$  or  $i \frac{\partial \psi}{\partial t} = \frac{E}{\hbar} \psi$ 

$$i\hbar \frac{\partial \psi}{\partial t} = E\psi$$

$$abla^2\psi+rac{2m(E-V)}{\hbar^2}\psi=0$$

Substitute the value of  $E \psi$ 

$$abla^2 \psi + rac{2m}{\hbar^2} i\hbar rac{\partial \psi}{\partial t} - V\psi = 0$$

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6. Calculate the eigen value and eigen function of a particle in one dimensional box by using Schrodinger equation.



Consider a particle mass is m.

It moves along x axis between two walls at x=0, x=a.

This particle is bouncing back and forth between the

Potential energy of the particle inside the box (V) = 0 Walls height is infinite. so the particle never comes out.

The potential function is square well potential.

The potential function, V(x) = 0 for 0 < x < a

 $V(x) = \propto for 0 \ge x \ge a$ 

The wave function 
$$\psi = 0 \text{ for } x \le 0$$
  
 $\psi = 0 \text{ for } x \ge a$ 

Because the wave function zero at walls of the box.(particle cannot exist on the walls)

To find the  $\psi$  of the particle inside the box at the limit x = 0 & x = a

Schrodinger wave equation in one dimension is  $\frac{d^2\psi}{dx^2} + \frac{2m}{\hbar^2}(E - V)\psi = 0$ 

Here V = 0,  $\frac{d^2\psi}{dx^2} + \frac{2m}{\hbar^2}E\psi = 0$ 

$$\frac{2m}{\hbar^2}E = k^2; \frac{4\pi^2 2m}{h^2}E = k^2 ork^2 = \frac{8\pi^2 mE}{h^2}$$
$$\frac{d^2\psi}{dx^2} + k^2 \psi = 0$$

The general solution of equ,  $\psi(x) = A \sin kx + B \cos kx$ 

A,B are unknown constants. These are obtained by applying boundary conditions.

(i) 
$$\psi = 0atx = 0$$
  
 $0 = A \sin 0 + B \cos 0$   
 $B = 0$   
(ii)  $\psi = 0atx = a$   
Asin ka = 0  
 $\therefore A = 0$  or Asin ka=0  
 $A \neq 0$  because  $B = 0$   
 $\therefore sin ka = 0$  if  $ka = n\pi$   
 $n =$  integer (1,2,3,4..) or  $k = \frac{n\pi}{a}$   
Squaring equ,  $k^2 = \frac{n^2 \pi^2}{a^2}$   
W.K.T  
 $\frac{n^2 \pi^2}{a^2} = \frac{8\pi^2 mE}{h^2}$   
The energy of the particle  $E E_n = \frac{n^2 h^2}{8ma^2}$   
 $\psi_n(x) = A \sin \frac{n\pi x}{a}$ 

 $E_n$ = Eigen value ;  $\psi_n$  = Eigen function

Hence The energy of the particle is quantised(the particles are associated with discrete energy values).

The value of A can be determined by normalisation of wave function. The probability density is  $\psi * \psi$ 

$$\psi * \psi = A \sin \frac{n\pi x}{a} \times A \sin \frac{n\pi x}{a}$$

 $\psi^* = \psi$  since wave function is real.

$$\psi^*\psi = A^2 \sin^2 \frac{n\pi x}{a}$$

The probability if finding the particle inside the box at the limit o to a,

$$\int_{0}^{a} \int \psi^{*} \psi dx = 1$$

Substitute the value of  $\psi * \psi$ ,  $\int_{0}^{a} \int A^{2} \sin^{2} \frac{n\pi x}{a} dx = 1$ 

$$A^{2} \int_{0}^{a} \frac{1 - \cos \frac{2n\pi x}{a}}{2} dx = 1$$

$$A^{2} \int_{0}^{a} \int \frac{dx}{2} - \frac{1}{2} \int_{0}^{a} \int \cos \frac{2n\pi x}{a} dx = 1$$

$$A^{2}\left[\frac{x}{2} - \frac{1}{2}\right] \left[\frac{\sin \frac{2n\pi x^{a}}{a}}{\frac{2n\pi}{a}}\right] = 1$$

$$A^2 \begin{bmatrix} \frac{x}{2} \end{bmatrix}_0^a = I$$

 $(A^{2}a/2)=1$  or  $A^{2}=2/a$  or

$$\psi_n = \sqrt{\frac{2}{a}} \sin \frac{n\pi x}{a} \qquad \qquad A = \sqrt{\frac{2}{a}}$$



Case (i) for n=1

$$\psi_1 = \sqrt{\frac{2}{a}} \sin \frac{\pi x}{a} \quad E_1 = \frac{h^2}{8ma^2}$$

Case (ii) for n=2

$$E_2 = \frac{4h^2}{8ma^2} = 4E_1$$

 $\psi_2 = \sqrt{\frac{2}{a}} \sin \frac{2\pi x}{a}$  The solution of one dimensional potential well is extended to 3 dimensional potential box. Here the particle can move

along three axis x, y, z.Consider a cube. All sides are equal in this case.



$$E_{nx_{nynz}} = E_{nx} + E_{ny} + E_{nz}$$
$$E_{nx_{nynz}} = \frac{n^2 h^2}{8ma^2} + \frac{n^2 h^2}{8ma^2} + \frac{n^2 h^2}{8ma^2}$$
$$E_{nx_{nynz}} = \frac{(n^2 x + n_y^2 + n_z^2)h^2}{8ma^2}$$

 $\psi_{nxnynz} = \psi_{nx}\psi_{ny}\psi_{nz}$ 

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$$= \sqrt{\frac{2}{a}} \sin \frac{n_x \pi x}{a} \sqrt{\frac{2}{a}} \sin \frac{n_y \pi x}{a} \sqrt{\frac{2}{a}} \sin \frac{n_z \pi x}{a}$$
$$\psi_{nxnynz} = \sqrt{\frac{8}{a^3}} \sin \frac{n_x \pi x}{a} \sin \frac{n_y \pi x}{a} \sin \frac{n_z \pi x}{a}$$

The combination of three quantum no's gives different eigen values and eigen functions.

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Example: If a state has quantum nos  $n_x=1, n_y=1, n_z=2$ 

$$E_{112} = \frac{6h^2}{8ma^2}$$
: Therefore eigen functions are  
$$\psi_{112} = \sqrt{\frac{8}{a^3}} \sin \frac{\pi x}{a} \sin \frac{\pi x}{a} \sin \frac{2\pi x}{a}$$
$$\psi_{121} = \sqrt{\frac{8}{a^3}} \sin \frac{\pi x}{a} \sin \frac{2\pi x}{a} \sin \frac{\pi x}{a}$$
$$\psi_{211} = \sqrt{\frac{8}{a^3}} \sin \frac{2\pi x}{a} \sin \frac{\pi x}{a} \sin \frac{\pi x}{a}$$



APPLIED OPTICS.

Interference:

It is based on The super position principle. Which states that, when two ion more light wave trains act Simultaneously on any particle is a medium. The particle is displaced due to the superposition of all the wave trains. Definition:

0

when two light waves from the sources superimposes on each other then the resultant amplitude à the region of superposition is different than the amplitude of the individual waves. This modification of light energy is change is amplitude is called as interference. Conditions for interference

- 1. There must be two sources are coherent is nature (same frequency, amplifiede, warelength)
- 2. They should have constant phase difference.
- s. The sources should be closer to each other and the distance between The sources and the screen must be larger.
- 4. for Constructure interference: path difference = n?
- 5 for destructive interference: path afference= (2n+1) 2/2

MICHELSON'S INTERFEROMETER

Principle:

The anylitude of light seam from a source is divided into two parts of equal intensities by partial reflection and transmission. These beams are then sent interes directions at right angles and are brought together after they suffer reflection from plane minors to produce interference fringer.



Construction:

-> M. & M2 are highly polished minors which are right angles to each other.

-> G1, G2 are optically plane gass platter of same thereness and placed provallel to each other.

by, and by plates are inclined at an angle 45° with M, 1M2

(Z)

Types of fringes:

(1) Circular tringes

when M2 is eractly respendicular to M, I the Vitual Emage, Mirror M, (image of M2) an ais film of Constant thisseness is enclosed between them.

S. M. Mary

Airfilm gives reflected beam to interface. The path difference depends upon the following factors. "" is separation between M, 2 M2

(ii Angle sistended on the eye (iii) inclination between M and Mi

path differences are 2d for 200000 5, different for different 52 valuer of 0 S., S2 > Virtuel Source due to M, & Mc'.

It die duistane 400 M, 4M2' then 2 dis distance 61m 5, 252

path difference the firstays = ediosis

No is again reflected by the serie- silvered glass Mr. is again reflected by the serie- silvered glass plate (9) 70 tal mats difference durtwo mys = 2 disso - N2

If the toral path difference is "ha, =) we receive bright Friges · (2n+1) 2 7 4 " dawn forges # ..

Case(1).

Shaped

----- ML

when M, and M2' Condider, the path difference is zero therefore the field of view is perfectly dorce.

weight to with

singe to sprive to state

NA PARA DO

----- M:

Case vij when M, is moved either way parallel to itself, widely spoked circular furges are produced.

width of fingers depends upon the path difference between the rays.

2) Localized finger: When minor Me is not exactly perpendicular to M, (m) if M, and the virtual minor M' are inclined. than The air film enclosed between them is wedge

The state of the s

For Smell i For Large public packs difference digit fringes (3) Localized utitelight fringes with so hibelight, the forgets are observed only when the path difference is very small. Central boys is derive and other friger are Coloured.

Applications of Michelson Interferometa It is used to determine 1. wavelength of the monochromatic light 2. refrective indees and thecaress of the various this transparent materials. 3. The difference the two neighboring waveleyths Determination of wavelength. If h is the hoot finges that crosses the centre of the field and it is the distance through which the nimor is moved. 1 20 coro = nd (might) Since a is very small 0 20 Standen and at would is 2d = nd . have do ha , A= 2d If A=1" ( only one crosses the centre) Enter Dezd. ..... Determination of Thereness of a this Transpreat medius Central fringe in the field of view is made to crinide In merdelson interferometer with the vertical cross wire and the position of the minnor M, NON the this transparent sheet of knows refraction is noted. index (p) is istroduced by the glass plate Ge and the memor M2. Due to new sheet introduction, a rath difference is much and the central pringe is shifted from

path difference - is 2/4-0 t. It & when to deversity 3 (p-1) t= n Auron ell je Anne more " a sin 2 = 29/2 and Shan when all all all & (m-1)t = MZd almost superior " The difference was no the terretory M-1)t=d 3. commence t = dThousand of (1-1) 5 A 11 to be a state thin sheet by the newlow Altwedge 1: 1 applications S Same Two glass plates are inclined at an ungle (0) by introducing a this material, forming a wedge shaped TO ais form. This form is illuminated by Sodiers light. Interference accurs between the two rays. is Reflected from the front surface id by internal reflection at the back surface Section Section Zmand any att only win of in matches to the party of the going have 29 STAR UK 30 anyther with strue S . 400 . 10 1 1 35 the true barry and the · mar Jos mar 145. is considered by the files place the to send I we to some the set of the set of the set of the Applications to trind the thread of material and and En al A manufactor handy to als

#### **LASER**

#### Introduction.

LASER stands for Light amplification by stimulated emission of radiation.

Laser is a device which emits a powerful, monochromatic collimated beam of light. The emitted light waves are coherent in nature.

#### **Characteristics of Laser:**

#### **1. Directionality**

Ordinary light spreads in all directions and its angular spread is 1m/m. But it is found that laser is highly directional and is angular spread is 1mm/m. For example, the laser beam can be focused to very long distance with a few divergence or angular spread.

#### Intensity:

Since an ordinary light spreads in all directions, the intensity reaching the target is very less. But in the case of laser, due to high directionality, the intensity of laser beam reaching the target is of high intense beam. For example, 1 mill watt power of He-Ne laser appears to be brighter than the sunlight.

#### 2. Monochromatic:

Laser beam is highly monochromatic; the wavelength is single, whereas in ordinary light like mercury vapour lamp, many wavelengths of light are emitted.

#### 4 Coherence:

It is an important characteristic of laser beam. In lasers the wave trains of same frequency are in phase, the radiation given out is in mutual agreement not only in phase but also in the direction of emission and polarization. Thus it is a coherent beam. Due to high coherence it results in an extremely high power.

2.1.3 Differences between ordinary light and Laser beam.

S.No	Ordinary light	Laser beams
1	In ordinary light the angular spread is more.	In laser beam the angular spread is less.
2	They are not directional.	They are highly directional.
3	It is less intense	It is highly intense
4	It is not a coherent beam and is not in phase.	It is a coherent beam and is in phase
5	The radiation are polychromatic	The radiations are monochromatic
6	Example: Sun light, Mercury vapor lamp	He- Ne Laser, Co <sub>2</sub> laser

#### Derive an expression for Einstein coefficients.

Different processes involved in optical beam emission

- 1. Induced or stimulated emission
- 2. Spontaneous emission
- 3. Stimulated emission
- 1. Stimulated absorption:

An atom in the lower energy level or ground state energy level  $E_1$ absorbs the incident photon radiation of energy  $\nu$  and goes to the higher energy level or excited level  $E_2$  as shown in figure. This process is called absorption.

If there are many numbers of atoms in the ground state then each atom will absorb the energy


from the incident photon and goes to the excited state. Q is energy density of incident radiation.

$$\frac{N_{ab}\alpha N_1 Q}{N_{ab} = B_{12}N_1 Q}$$
-----(1)

Where,  $B_{12}$  is proportionality constant.

2. Spontaneous emission:

The atom in the excited state returns to the ground state by emitting a photon of energy  $E = (E_2 - E_1) = hv$ 

Spontaneously without any external triggering as shown in the figure.



This process is known as spontaneous emission. Such an emission is random and is independent of incident radiation. If  $N_1$  and  $N_2$  are the numbers of atoms in the ground state (E<sub>1</sub>) and excited state (E<sub>2</sub>) respectively, then

$$\frac{N_{sp}\alpha N_2}{N_{sp} = A_{21}N_2}$$
-----(2)

Where,  $A_{21}$  is proportionality constant.

3. Stimulated Emission:

The atom in the excited state can also return to the ground state by external triggering or inducement of photon thereby emitting a photon of energy equal to the energy of the incident photon, known as stimulated emission. Thus results in two photons of same energy, phase difference and of same directionality as shown.



$$N_{st} \alpha N_2 Q$$
$$N_{st} = B_{21} N_2 Q$$

Where,  $B_{21}$  is proportionality constant.

 $A_{12}$ ,  $B_{12}$  and  $B_{21}$  are known as Einstein's coefficients.

Under equilibrium condition,

$$Q = \frac{A_{21}}{B_{21}} \frac{1}{\left(\frac{B_{12}}{B_{21}}\right)} e^{\frac{h\nu}{kT}} - 1$$
(8)

Planck's radiation formula

$$Q = \frac{8\pi h \upsilon^3}{c^3} \frac{1}{e^{h\upsilon/kT} - 1} - \dots - \dots - (9)$$

comparing equation (8) and (9)

$$\left(\frac{B_{12}}{B_{21}}\right) = 1$$

$$B_{12} = B_{21} - \dots - (10)$$

$$\frac{A_{21}}{B_{21}} = \frac{8\pi h \upsilon^3}{c^3} - \dots - (11)$$

 $B_{12} = B_{21}$  are Einstein coefficients.

CO2 Molecular gas laser

It was the first molecular gas laser developed by Indian born American scientist Prof.C.K.N.Pillai.

It is a four level laser and it operates at 10.6  $\mu m$  in the far IR region. It is a very efficient laser.

## Energy states of CO<sub>2</sub> molecules.

A carbon dioxide molecule has a carbon atom at the center with two oxygen atoms attached, one at both sides. Such a molecule exhibits three independent modes of vibrations. They are

- a) Symmetric stretching mode.
- b) Bending mode
- c) Asymmetric stretching mode.

# a. Symmetric stretching mode

In this mode of vibration, carbon atoms are at rest and both oxygen atoms vibrate simultaneously along the axis of the molecule departing or approaching the fixed carbon atoms.



# **b.Bending mode:**

In this mode of vibration, oxygen atoms and carbon atoms vibrate perpendicular to molecular axis.

# c. Asymmetric stretching mode:



In this mode of vibration, oxygen atoms and carbon atoms vibrate asymmetrically, i.e., oxygen atoms move in one direction while carbon atoms in the other direction.

## **Principle:**

The active medium is a gas mixture of  $CO_2$ , N2 and He. The laser transition takes place between the vibrational states of  $CO_2$  molecules.



#### **Construction**:

It consists of a quartz tube 5 m long and 2.5 cm in the diameter. This discharge tube is filled with gaseous mixture of  $CO_2$  (active medium), helium and nitrogen with suitable partial pressures.

The terminals of the discharge tubes are connected to a D.C power supply. The ends of the discharge tube are fitted with NaCl Brewster windows so that the laser light generated will be polarized. Two concave mirrors one fully reflecting and the other partially form an optical resonator.

# Working:



Figure shows energy levels of nitrogen and carbon dioxide molecules.

When an electric discharge occurs in the gas, the electrons collide with nitrogen molecules and they are raised to excited states. This process is represented by the equation

$$N_2 + e^* = N_2^* + e$$

 $N_2$  = Nitrogen molecule in ground state  $e^*$  = electron with kinetic energy

 $N_2^*$  = nitrogen molecule in excited state e= same electron with lesser energy

Now  $N_2$  molecules in the excited state collide with  $CO_2$  atoms in ground state and excite to higher electronic, vibrational and rotational levels.

This process is

represented by the equation  $N_2^* + CO_2 = CO_2^* + N_2$ 

 $N_2^* = Nitrogen molecule in$ excited state.  $CO_2 = Carbon$ dioxide atoms in ground state  $CO_2^* = Carbon$  dioxide atoms in excited state  $N_2 =$ Nitrogen molecule in ground state.

Since the excited level of nitrogen is very close to the  $E_5$  level of  $CO_2$  atom, population in  $E_5$  level increases.

As soon as population inversion is reached, any of the spontaneously emitted photon will trigger laser action in the tube. There are two types of laser transition possible.

#### I. **Transition E**<sub>5</sub> to E<sub>4</sub>:

This will produce a laser beam of wavelength 10.6µm

# **II. Transition E**<sub>5</sub> to E<sub>3</sub>

This transition will produce a laser beam of wavelength 9.6µm. Normally 10.6µm transition is more intense than 9.6µm transition. The power output from this laser is 10kW.

## **Characteristics:**

- 1. Type: It is a molecular gas laser.
- Active medium: A mixture of CO<sub>2</sub>, N<sub>2</sub> and helium or water vapour is used as active medium
- 3. Pumping method: Electrical discharge method is used for Pumping action
- 4. Optical resonator: Two concave mirrors form a resonant cavity
- 5. Power output: The power output from this laser is about 10kW.
- 6. Nature of output: The nature of output may be continuous

wave or pulsed wave.

 Wavelength of output: The wavelength of output is 0.6μm and 10.6μm.

# Advantages:

- 1. The construction of  $CO_2$  laser is simple
- 2. The output of this laser is continuous.
- 3. It has high efficiency
- 4. It has very high output power.
- 5. The output power can be increased by extending the length of the gas tube.

# Disadvantages:

- 1. The contamination of oxygen by carbon monoxide will have some effect on laser action
- 2. The operating temperature plays an important role in determining the output power of laser.
- 3. The corrosion may occur at the reflecting plates.
- 4. Accidental exposure may damage our eyes, since it is invisible (infra red region) to our eyes.

# Applications:

- High power CO<sub>2</sub> laser finds applications in material processing, welding, drilling, cutting soldering etc.
- The low atmospheric attenuation (10.6µm makes CO<sub>2</sub> laser suitable for open air communication.
- 3. It is used for remote sensing
- 4. It is used for treatment of liver and lung diseases.
- 5. It is mostly used in neuro surgery and general surgery.
- 6. It is used to perform microsurgery and bloodless operations.

# 6. Explain the construction and working of Homo-junction semiconductor diode laser

# Principle:

When a p-n junction diode is forward biased, the electrons from n – region and the holes from the p- region cross the junction and recombine with each other. During the

recombination process, the light radiation (photons) is released from a certain specified direct band gap semiconductors like Ga-As. This light radiation is known as recombination radiation. The photon emitted during recombination stimulates other electrons and holes to recombine. As a result, stimulated emission takes place which produces laser.



#### **Construction:**

Figure shows the basic construction of semiconductor laser. The active medium is a p-n junction diode made from the single crystal of gallium arsenide. This crystal is cut in the form of a platter having thickness of 0.5µmm.

The platelet consists of two parts having an electron conductivity (n-type) and hole conductivity (p-type).

The photon emission is stimulated in a very thin layer of PN junction (in order of few microns). The electrical voltage is applied to the crystal through the electrode fixed on the upper surface.

The end faces of the junction diode are well polished and parallel to each other. They act as an optical resonator through which the emitted light comes out.

When the PN junction is forward biased with large applied voltage, the electrons and holes are injected into junction region in considerable concentration

The region around the junction contains a large amount of electrons in the conduction band and a large amount of holes in the valence band.

If the population density is high, a condition of population inversion is achieved. The electrons and holes recombine with each other and this recombination's produce radiation in the form of light.

When the forward – biased voltage is increased, more and more light photons are emitted and the light production instantly becomes stronger. These photons will trigger a chain of stimulated recombination resulting in the release of photons in phase.

The photons moving at the plane of the junction travels back and forth by reflection between two sides placed parallel and opposite to each other and grow in strength. After gaining enough strength, it gives out the laser beam of wavelength 840 nm.

# **Characteristics:**

- 1. Type: It is a solid state semiconductor laser.
- 2. Active medium: A PN junction diode made from single crystal of gallium arsenide is used as an active medium.
- **3. Pumping method**: The direct conversion method is used for pumping action
- 4. **Power output:** The power output from this laser is 1mW.
- 5. Nature of output: The nature of output is continuous wave or pulsed output.
- 6. Wavelength of Output: gallium arsenide laser gives infrared radiation wavelength 830 to 850 nm.

# Advantages:

- 1. It is very small in dimension. The arrangement is simple and compact.
- 2. It exhibits high efficiency.
- 3. The laser output can be easily increased by controlling the junction current
- 4. It is operated with lesser power than ruby and CO<sub>2</sub> laser.
- 5. It requires very little auxiliary equipment
- 6. It can have a continuous wave output or pulsed output.

# Disadvantages:

- 1. It is difficult to control the mode pattern and mode structure of laser.
- 2. The output is usually from 5 degree to 15 degree i.e., laser beam has large

divergence.

- 3. The purity and monochromacity are power than other types of laser
- 4. Threshold current density is very large  $(400 \text{ A/mm}^2)$ .
- 5. It has poor coherence and poor stability.

# **Application:**

- 1. It is widely used in fiber optic communication
- 2. It is used to heal the wounds by infrared radiation
- 3. It is also used as a pain killer
- 4. It is used in laser printers and CD writing and reading.

7. Explain the construction and working of hetero-junction semiconductor diode laser

A pn junction made up of the different materials in two regions ie., n type and p type is known ad hetrojunction.

# **Principle:**

When a PN junction diode is forward biased, the electrons from the n region and holes from the p region recombine with each other at the junction. During recombination process, light is released from certain specified direct band gap semiconductors.

A layer of Ga-As p – type (3<sup>rd</sup> layer) will act as the active region. This layer is sand witched between two layers having wider band gap viz GaAlAs-p – type (2<sup>nd</sup> layer) and **GaAlAs**-n- type (4<sup>th</sup> layer).

The end faces of the junctions of 3<sup>rd</sup> and 4<sup>th</sup> layer are well polished and parallel to each other. They act as an optical resonator.



# Working:

When the PN junction is forward biased, the electrons and holes are injected into the junction region. The region around the junction contains large amount of electrons in the conduction band and holes in the valence band.

Thus the population inversion is achieved. At this stage, some of the injected charge carriers recombines and produce radiation in the form of light.

When the forward biased voltage is increased, more and more light photons are emitted and the light intensity is more. These photons can trigger a chain of stimulated recombination's resulting in the release of photons in phase.

The photons moving at the plane of the junction travels back and forth by reflection between

two sides and grow its strength. A coherent beam of laser having wavelength nearly 8000 out

from the junction region.

S.No	TITLE		Description
------	-------	--	-------------

1.	Туре	:	It is a heterojunction semiconductor laser
2.	Active medium	:	PN junctions made from different layers.
3.	Pumping method	:	Direct conversion method
4.	Power output	:	The power output of laser beam is 1 mW
5.	Nature of the Output	:	Continuous wave form
6.	Wavelength of the output	:	0 Nearly 8000 A

# Advantages:

- 1. It produces continuous wave output.
- 2. The power output is very high.

# **Disadvantages:**

- 1. It is very difficult to grow different layers of PN junction.
- 2. The cost is very high.

# **Applications:**

- 1. This type of laser is mostly used in optical applications
- 2. It is widely used in computers, especially on CD-ROMs.

# **APPLICATIONS OF LASER**

The most significant applications of lasers include:

- Lasers in medicine
- Lasers in communications
- Lasers in industries
- Lasers in science and technology
- Lasers in military

# Lasers in Medicine

1. Lasers are used for bloodless surgery.

- 2. Lasers are used to destroy kidney stones.
- 3. Lasers are used in cancer diagnosis and therapy.
- 4. Lasers are used for eye lens curvature corrections.
- 5. Lasers are used in fiber-optic endoscope to detect ulcers in the intestines.
- 6. The liver and lung diseases could be treated by using lasers.
- 7. Lasers are used to study the internal structure of microorganisms and cells.
- 8. Lasers are used to produce chemical reactions.
- 9. Lasers are used to create plasma.
- 10. Lasers are used to remove tumors successfully.
- 11. Lasers are used to remove the caries or decayed portion of the teeth.
- 12. Lasers are used in cosmetic treatments such as acne treatment, cellulite and hair removal.

Lasers in Communications

- Laser light is used in optical fiber communications to send information over large distances with low loss.
- 2. Laser light is used in underwater communication networks.
- 3. Lasers are used in space communication, radars and satellites.

# Lasers in Industries

- 1. Lasers are used to cut glass and quartz.
- Lasers are used in electronic industries for trimming the components of Integrated Circuits (ICs).
- 3. Lasers are used for heat treatment in the automotive industry.

- Laser light is used to collect the information about the prefixed prices of various products in shops and business establishments from the bar code printed on the product.
- Ultraviolet lasers are used in the semiconductor industries for photolithography.
   Photolithography is the method used for manufacturing printed circuit board (PCB) and microprocessor by using ultraviolet light.
- Lasers are used to drill aerosol nozzles and control orifices within the required precision.

Lasers in Science and Technology

- 1. A laser helps in studying the Brownian motion of particles.
- 2. With the help of a <u>helium-neon</u> laser, it was proved that the velocity of light is same in all directions.
- 3. With the help of a laser, it is possible to count the number of <u>atoms</u> in a substance.
- Lasers are used in computers to retrieve stored information from a Compact Disc (CD).
- 5. Lasers are used to store large amount of information or data in CD-ROM.
- Lasers are used to measure the pollutant gases and other contaminants of the atmosphere.
- 7. Lasers helps in determining the rate of rotation of the earth accurately.
- 8. Lasers are used in computer printers.
- Lasers are used for producing three-dimensional pictures in space without the use of lens.
- 10. Lasers are used for detecting earthquakes and underwater nuclear blasts.

11. A gallium arsenide diode laser can be used to setup an invisible fence to protect an area.

Lasers in Military

- 1. Laser range finders are used to determine the distance to an object.
- 2. The ring laser gyroscope is used for sensing and measuring very small angle of rotation of the moving objects.
- 3. Lasers can be used as a secretive illuminators for reconnaissance during night with high precision.
- 4. Lasers are used to dispose the energy of a warhead by damaging the missile.
- 5. Laser light is used in LIDAR's to accurately measure the distance to an object.

# **FIBER OPTICS**

An optical fibre is made up of three concentric parts.

Core :

(made of glass i. e silicon dioxide or plastic)- Thin centre of the fiber . The light will travel through it. It has high refractive index.

Cladding:

( made of glass plastic) - Material surrounding the core. It reflects the incident light. It has low refractive index than core

Jacket : Outer cover to product the fiber from damage.



Total internal reflection: When the angle of incidence exceeds the critical angle the incident ray is reflected in the same medium. This phenomenon is called total internal reflection.

Critical angle: When light travels from denser medium to rarer medium at a particular angle of incidence angle called the critical angle, the ray emerges along the surface of separation.

Case 1: When  $\theta_1 < \theta_c$ , The light will refract through cladding.

Case 2: When  $\theta_1 = \theta_c$ , The light will travel along the surface between core and cladding.

Case3: When  $\theta_1 > \theta_c$ , The light will be reflected totally

Expression for critical angle.

It is derived from snell's law  $n_1 \sin \theta_1 = n_1 \sin \theta_2$ 

For total internal reflection

```
\theta_1 = \theta_c \text{ and } \theta_2 = 90^\circ
n_1 \sin \theta_c = n_2 \sin 90^\circ
\sin \theta_c = (n_2/n_1) \sin 90^\circ
\sin \theta_c = (n_2/n_1) \text{ or }
\theta_c = \sin^{-1}(n_2/n_1)
```

Conditions for total internal reflection:

Light should travel from denser medium to rarer medium.

The angle of incidence on core should be greater than the critical angle.

The refractive index of the core should be greater than the refractive index of cladding.

2. Derive an expression for numerical aperture and acceptance angle.

Acceptance angle: The maximum angle with which a ray of light can enter through one end of the fiber and still be total internally reflected is called acceptance angle.

Numerical aperture: The sine of acceptance angle is known as numerical aperture. It shows the light collecting efficiency of fiber.



The incident light AO enters into an optical fiber. Here  $\theta_1$  is refracted angle in the core and  $\theta_0$  is light entering angle into the fiber.

If a light ray enter into fiber at an angle of incidence less than  $\theta_0$ , The light will undergo the total internal reflection . Here the angle of incidence is more than critical angle.

Where  $n_1$  is the refractive index of core,

n2 is the refractive index of cladding and

no is refractive index of air.

Applying snell's law

 $n_0 sin \theta_0 = n_1 sin \theta_1$ 

 $\sin \theta_0 = (n_1/n_0) \sin \theta_1$ 

# sin θ₀=( n₁/n₀) √1-cos² θ₁

At the point B on the incidence of core and cladding

 $\theta_c = 90 - \theta_1$ 

#### Applying snell's law

 $n_1 \sin(90^{\circ} - \theta_1) = n_2 \sin 90^{\circ}$  or

 $n_1 cos \theta_1 = n_2$ 

#### cos θ1=n2/n1

 $\sin \theta_0 = (n_1/n_0) \sqrt{1 - (n_2^2/n_1^2)}$ 

 $\sin \theta_0 = (n_1/n_0) \sqrt{(n_1^2 - n_2^2)/n_1^2}$ 

sin θ₀= √(n₁²-n₂²)/n₀

 $\theta_0 = \sin^{-1} \sqrt{(n_1^2 - n_2^2)/n_0}$  or

Refractive index of air  $(n_0) = 1$ 

θ₀= sin-¹√(n₁²-n₂²)

 $\theta_0$  - is called Acceptance angle

**Numerical Aperture:** 

It is simply denoted as NA.

NA= sin  $\theta_0$ 

NA= sin(sin⁻1√(n₁²-n₂²)) = √(n₁²-n₂²)

4.Discuss various types of optical fibers



On the basis of materials the fibers can be classified into two types. i.e Glass and Plastic .

Glass fiber is made up of fusing mixture of silica and oxides.

Ex. Core- $SiO_2$ , Cladding –  $P_2O_3$ – $SiO_2$ .

Plastic fiber is made up of Plastics.

Ex. Core – Polystyrene , Cladding – Methyl Metha crylates .

On the basis of Modes the fiber can be classified into two types. i.e Single mode and Multimode

In **single mode** only one mode is sent through the fiber. This kind of fiber core has small diameter.

There is a small refractive index difference between core and cladding

Laser diodes are used here. No dispersion in this case. Cost is high Because fabrication is difficult. 50-125 µm





In multi mode many mode is sent through the fiber.

This fiber has large core diameter. Multi mode dispersion is here. Cost is low.



50-200µḿ

On the basis of refractive index the fiber is classified into two types. i.e step index and graded index.

In step index fiber is categorised into two types as single mode and multi mode.

## Step index single mode fiber:

It has small core diameter and Numerical aperture.

It provides only one mode.

Laser diodes are used to signal transmission.

It is mainly used for Long distance communication and submarine systems.

## Step index multi mode fiber:

It has Large core diameter and High numerical aperture.

Many mode is accepted here.

Bandwidth is low.

LED's are used.

Widely used in low bandwidth required data links.

#### Graded index multi mode fiber:

Here, The refractive index is maximum in core and gradually decreases towards the interface of core & cladding.

Core diameter is high.

Dispersion loss is minimised.

It has medium level band width.

Numerical aperture is low.LED or laser is used here.



5. Describe the optical fiber communication in detail with a neat diagram.

The main parts of the fiber optic communication system are

1.Information source

{Audio or Video signal}

2.Transmitter

{Light source, Encoder, Amplifier, Modulator}

3.Guiding medium ( optical fiber )

4.Repeater

{Detector, Amplifier, Optical Source}

# **5.Receiver**

# {Detector, Demodulator, Decoder, Amplifier}

# 6.Receiving end

- # The information signal source may be voice, music or in any form. Here it is analog.
- # Transmitter consists of a encode , Amplifier ,Light source ,Modulator.
- # Encoder is to convert the analog into digital signal.
- # Light source may be LED or Laser. It converts Digital pulses into optical pulses.

# Optical Fiber is used as Guiding media. It conducts signal by making total internal reflection.

- # Connector is used to couple the Transmitter and Fiber.
- # Repeater block is added to Produce degraded less signal.
- # Receiver consists of Decoder, Demodulator, Amplifier.
- # Decoder is to convert the digital into analog signal.
- # Finally one can receive the same signal at receiving end as given as input.

# 6. Describe the construction and working of an optical source.



- It converts electrical energy into optical energy.
- A N- type layer is formed on a substrate. A P-type layer is deposited on it by diffusion.
- The bottom of the substrate is coated with gold film for reflection.
- It is a semiconductor device. It emits light When it is connected in forward bias.
- In forward bias depletion layer width is reduced , raising the potential energy on the N- side and reducing that on the P-side.
- Photon emission takes place when the recombination of holes and electrons.
- There are three stage in LED process.
- Excitation or injection Energy of carriers is raised by forward bias.
- Recombination Most of the carriers give up their excess energy as photons.
- Extraction Generated Photons leave from the semiconductor with desired optical stimulus.

## Advantages:

- Small in size
- Light intensity is controlled by varying the current.
- It is rugged. Hence we can use easily.
- It can operate over a wide range of temperature.
- ON- OFF is easy.
- It is available in different colours.
- Low voltage is enough for its operation.
- Brightness is sufficient.

#### **Disadvantages:**

- It is not suited for large area display.
- It doesn't have any special Characters like LASER.

7. Describe the construction and working of Detectors.

It converts optical energy into electrical energy. On the basis of electrical energy required the detectors are classified as follows.PIN Diode, Avalanche photo diode (APD).



Positive - intrinsic - negative diode. ( PIN )

I – region is neutral.

P and n regions are heavily doped.

Here the i region is lightly doped with n type material.

I region is made as large as possible to receive large no. of photons.

It works in Reverse bias.

When light is illuminated the electron hole pairs are generated.

These pairs are accelerated by applied electric field.

Due to reverse bias the i-region gets widen.

When the incident photon energy equal to greater than band gap energy of diode, the electron – hole pairs are formed by absorbing photons energy.

The generated photo current is directly proportional to the applied optical power.



It is a more sensitive device. Here large amount of electron – hole pairs are generated due to High reverse voltage is applied .

- Electron hole pairs gain energy from high field and colloid with valence band electrons. This process multiplies the charge carriers in number. This is known as Avalanche effect.
- It consists of four layers. i.e n p i p layers. It has a design as like p n diode .Instead of single p, it has 2 p- regions and 1 intrinsic region.
- The two p- regions and n- region are heavily doped. The intrinsic region is lightly doped with P.Due to reverse bias, the intrinsic region gets widen.
   Photons are illuminated on i – region. This produces electron – hole pairs.

# Crystal Physics – Unit 5

# Formula

S.No	Description
1.	$Packing factor = \frac{Volume \ occupied \ by \ the \ total \ no.of atoms/unitcell}{Total \ volume \ of \ the \ unitcell} = \frac{v}{V}$
2.	Atomic radius of simple cubic crystal $r = a/2$
3.	Atomic radius of body centred cubic $r = \frac{\sqrt{3}a}{4}$
4.	Atomic radius of Face centred cubic $r = \frac{a\sqrt{2}}{4}$
5.	Atomic radius of Hexagonal closely packed structure $r = a/2$
7.	Atomic radius of Diamond structure atomic radius $r = a\sqrt{3/8}$
8.	Inter-planar distance $d = \frac{a}{\sqrt{(h^2 + k^2 + l^2)}}$

# Part- A

# 1. Classify the materials in terms of structure.

Solids are broadly classified into two types based on the atomic structures.



- Crystal Atoms or molecules are arranged in regular fashion throughout the crystal. ex-Ag, cu, Pt, Au, Ge, Cd, Fe
- Amorphous Atoms or molecules are arranged in irregular pattern throughout the crystal. ex- Rubber, plastics, glass.

## 2. What is a space lattice?

Lattice is defined as an array of imaginary points. It represents the location of atoms or molecules. Every lattice point is identical in all respects. A three dimensional collection of points in space are called space lattice.

## 3. What is basis?

A crystal structure associated an assembly of atoms or molecules with every lattice point. This unit assembly is called basis.

Lattice+ Basis = crystal structure.

## 4. Define lattice planes.

A set of parallel and equally spaced planes in a space lattice formed w.r.t the lattice points is called lattice planes.

## 5. Define unit cell.

The smallest portion of a space lattice which can generate the complete crystal by repeating its own dimensions in various directions is called unit cell.

OA=a, OB=b, OC=c are the dimensions of the unit cell.

The angles between a,b; b.c; c,a are denoted by  $\gamma$ ,  $\beta$ ,  $\alpha$ .

 $\gamma, \beta, \alpha$  are interfacial angles.

X, Y, Z are crystallographic axes.



#### 5. Define primitive cell.

When the unit cell contains lattice points only at the corners, it is called a primitive cell. A minimum volume unit cell.

#### 6. What are Bravais lattices?

Scientist Bravais introduced the space lattice idea to show that there are only 14 ways of arranging points in space so that the environment looks same from each point. These 14 space lattices are called bravais lattices.

#### 7. Define Effective number or no.of atoms per unit cell.

It is defined as total no.of atoms present in or shared by an unit cell .

#### 8. Define atomic radius.

It is defined as the half of the distance between any two nearest neighbour atoms.

# 9. Define packing factor.

 $Packing factor = \frac{Volume \ occupied \ by \ the \ total \ no.of atoms/unitcell}{Total \ volume \ of \ the \ unitcell} = \frac{v}{V}$ 

## 10. What are miller indices?

Scientist miller introduced a system (set of 3 numbers) to designate a plane in a crystal, is called miller indices of concerned plane.

These are three possible integers which have the same ratios as the reciprocal of the intercepts of the plane concerned along the 3 axes.

## 11. Define inter atomic distance and inter planar distance?

The distance between any two atoms is called inter-atomic distance.

The distance between any two planes is called inter-planar distance.

# 12. Role of imperfections in plastic deformation:

If a crystal is deformed by the applications of stresses, now it returns to its original state upon removal of the stresses, then the deformation is said to be elastic.

If that crystals retains its original state (deformed state), then it is said to be plastic.

In general, in most of the crystals the plastic deformations results from the slip of one part of the crystal relative to another.

Slip is caused by the presence of dislocation, a connections between plastic deformation and dislocations must obviously exist.

#### Part - B

#### 1. Describe the seven types of crystal system and fourteen types Bravais lattices?

S.no	Crystal	Unit cell parameters	Bravais lattice
	system		
1	Triclinic	$a \neq b \neq c$	Simple
		$\alpha \neq \beta \neq \gamma \neq 90^{\circ}$	
2	Monoclinic	$a \neq b \neq c$	Simple, Base –
		$\alpha \neq \beta = 90^{\circ} \neq \gamma$	centred





2. Calculate the no.of atoms per unit cell, coordination number, atomic radius, packing factor for simple cubic, Body centred cubic, Face centred cubic Structures.

# (i) SIMPLE CUBE



**No.of atoms per unit cell:** Cube has 8 corner atoms. Each corner atom is shared by 8 unit cells.

Therefore each atom contributes 1/8 of its part to a single unit cell.

Total no. of atoms/ unit cell =  $\frac{1}{8} \times$  Total no of corner atoms =  $\frac{1}{8} \times 8 = 1$  atom

#### **Co-ordination number:**

There are 4 nearest atoms in horizontal plane and 2 nearest atoms in vertical plane. Therefore coordination number for cubic is 6.



Atomic radius: Here all atoms are touch each other. The distance between two atoms is equal to the edge of the cube.

Side of the unit cell. r- radius of the atom. Therefore r = a/2



No.of atoms per unit cell= 1

Volume of 1 atom = 
$$\frac{4}{3}\pi r^3$$

If 'a' is a side of unit cell, Volume of the unit cell  $V=a^3$ 

Packing factor = v/V

$$PF = \frac{\frac{4}{3}\pi r^3}{a^3} = \frac{\frac{4}{3}\pi r^3}{8r^3} = \frac{4\pi r^3}{24r^3} = \frac{\pi}{6} = 0.523$$

#### PF = 52%

52% of the volume is occupied by the atoms ,48% volume is empty. Ex: Polonium.



In this case, the unit cell has eight corner atoms and one atom at the centre. Each corner atom is shared by eight unit cells. But the atom at the centre is exclusively for particular unit cell.

**No.of atoms per unit cell:** 8 corner atoms shared by 8 unit cells. Body centred atom is only for 1 unit cell. Therefore Total no.of atoms =  $(\frac{1}{8} \times 8 = 1atom) + 1atom = 2atoms$ 

## **Co-ordination number:**



Here corner atom do not touch each other .But all corner atoms touch the body centred atom. Hence the coordination number of BCC is 8.



а

consider the corner atoms at A,G and centred atom O. In triangle ABC,

$$AC^{2} = AB^{2} + BC^{2}$$

$$AC^{2} = a^{2} + b^{2}$$

$$AC^{2} = AB^{2} + BC^{2}$$

$$AC^{2} = 2a^{2}$$

$$AG = r + 2r + r = 4r$$
squarring on both sides
$$AG^{2} = (4r)^{2}$$

$$In\Delta \quad ACG,$$

$$AG^{2} = AC^{2} + CG^{2}$$

$$\therefore (4r)^{2} = 2a^{2} + a^{2} = 3a^{2}$$

$$r^{2} = \frac{3a^{2}}{4^{2}};$$

$$r = \frac{\sqrt{3}a}{4}$$

# Packing factor:

No.of atoms per unit cell = 2

Volume of 2 atoms,  $v = 2 \times \frac{4}{3} \pi r^3$ 

Side of the unit cell  $a = \frac{4r}{\sqrt{3}}$ 

Volume of the unit cell  $V=a^3$ 

Packing factor P.F = v/V

$$P.F = \frac{2 \times \frac{4}{3}\pi r^3}{a^3}$$

substitute a value,

$$P.F = \frac{2 \times \frac{4}{3}\pi r^{3}}{\left[\frac{4r}{\sqrt{3}}\right]^{3}} = \frac{\frac{8}{3}\pi r^{3}}{\frac{64r}{3\sqrt{3}}} = \frac{8}{3}\pi r^{3} \times \frac{3\sqrt{3}}{64r^{3}} = \frac{\sqrt{3}\pi}{8} = 68\%$$

68% of volume is occupied by atoms and 32% of volume is empty in BCC.

# (ii)FACE CENTRED CUBE:

Here the unit cell has 8 corner atoms and in addition 1 atom at each face. Since each atom has 12 nearest neighbours, it is closely packed.



**No.of atoms per unit cell:** There are 8 corner atoms. Each corner atom is shared by 8 unit cells. The contribution of corner atoms for a particular unit cell =  $\frac{1}{8} \times 8 = 1$  atom

There are 6 face centred atoms. Each atom is shared by 2 unit cells.

The contribution of face centred atoms to the unit cell =  $\frac{1}{2} \times 6 = 3$  atoms

 $\therefore$  The total no.of atoms in the unitcell = 1 + 3 = 4

# **Co-ordination number:**


Consider a centre atom X. It has 4 nearest neighbour atoms along in x-plane, 4 nearest neighbour atoms along in y-plane and 4 more atoms in z plane.

Therefore total no.of nearest atoms to any corner atom = 12

Coordination number = 12



Atoms touch each other along the diagonal of any face.

In right angle 
$$ABC$$
,  
 $AC^2 = AB^2 + BC^2$ 

$$(r+2r+r)^{2} = a^{2} + a^{2}$$
$$16r^{2} = 2a^{2}$$
$$\sqrt{r^{2}} = \frac{\sqrt{2a^{2}}}{\sqrt{16}}$$
$$r = \frac{a\sqrt{2}}{4}$$

### Packing factor:

No.of atoms per unit cell = 4

Volume of 4 atoms , 
$$v = 4 \times \frac{4}{3} \pi r^3$$

Side of the unit cell  $a = \frac{4r}{\sqrt{2}}$ 

Volume of the unit cell  $V=a^3$ 

Packing factor P.F = v/V

$$P.F = \frac{4 \times \frac{4}{3}\pi r^3}{a^3}$$

substitute a value,

$$P.F = \frac{4 \times \frac{4}{3}\pi r^{3}}{\left[\frac{4r}{\sqrt{2}}\right]^{3}} = \frac{\frac{16}{3}\pi r^{3}}{\frac{64r}{2\sqrt{2}}^{3}} = \frac{16}{3}\pi r^{3} \times \frac{2\sqrt{2}}{64r^{3}} = \frac{\pi\sqrt{2}}{6} = 74\%$$

**3.** Calculate the no. of atoms per unit cell, coordination number, atomic radius, packing factor for Hexagonal close-packed Structure.



There are 12 corner atoms in HCP structure. It has hexagonal prism shape. Each hexagon face possess an atom at its centre. 3 atoms symmetrically arranged in the body of the unit cell. Atoms are arranged in three layers. Top and bottom layer has 7 atoms for each. Middle layer has 3 atoms.

#### No.of atoms per unit cell:

Each corner atom is shared by 6 unit cells.

No.of atoms in the top hexagonal plane = 
$$\frac{1}{6} \times 6 = 1$$

No.of atoms in the bottom hexagonal plane =  $\frac{1}{6} \times 6 = 1$ 

Central atom is shared by 2 unit cells.

No.of central atoms in both top and bottom hexagonal plane =  $\frac{1}{2} \times 2 = 1$ 

There are 3 atoms at middle layer of unit cell. these are not shared by other unit cells.

Total no.of atoms in a HCP unit cell = 1+1+1+3=6

### **Co-ordination number:**



Consider a central atom in middle layer, It has 6 nearest corner atoms. 3 nearest atoms above and 3 nearest atoms below to the concerned layer.

Therefore coordination number = 12.

#### Atomic radius:

Atoms touch each other along the edges of the hexagonal.

Therefore a = 2r.

Atomic radius r=a/2



## Packing factor:

Volume of the atoms in a unit cell = No.of atoms x volume of one atom =  $6 X \frac{4}{3} \pi r^{3}$ 

Substituting r = a/2

$$v = \frac{24}{3}\pi \left[\frac{a}{2}\right]^{3}$$
$$v = \frac{24\pi a^{3}}{3 \times a^{3}} = \frac{24\pi a^{3}}{3 \times 8} = \pi a^{3}$$
Volume of the unit cell (V):

Calculation of c/a ratio:



- c Height of the unit cell of HCP.
- a Distance between 2 neighbouring atoms.

$$\Delta ABY, COS 30^{\circ} = \frac{AY}{AB}$$

$$AY = ABCOS 30^{\circ} = \frac{a\sqrt{3}}{2}$$

$$AX = \frac{2}{3}AY = \frac{2}{3}\frac{a\sqrt{3}}{2} = \frac{a}{\sqrt{3}}$$

$$In\Delta AXC, AC^{2} = AX^{2} + CX^{2}$$

$$Substitute \quad values \quad AC = a, AX = \frac{a}{\sqrt{3}}, CX = \frac{c}{2}$$

$$a^{2} = \left[\frac{a}{\sqrt{3}}\right]^{2} + \left[\frac{c}{2}\right]^{2}$$

$$a^{2} = \frac{a^{2}}{3} + \frac{c^{2}}{4}; \frac{c^{2}}{4} = a^{2} - \frac{a^{2}}{3}$$

$$\frac{c}{4}^{2} = \frac{2a^{2}}{3}or\frac{c}{a^{2}}^{2} = \frac{8}{3}$$

$$\frac{c}{a} = 1.633$$

Area of the base =6 X Area of triangle AOB Area of triangle AOB = 1/2 X (BO)(AY)

Area of triangle  $AOB = \frac{1}{2} \times a \times \frac{a\sqrt{3}}{2} = \frac{a^2\sqrt{3}}{4}$ Area of base  $= 6 \times \frac{a^2\sqrt{3}}{4} = \frac{a^23\sqrt{3}}{2}$ Volume of the unit cell(HCP) = base area × height  $V = \frac{a^23\sqrt{3}}{2} \times c$  P.F = v/V  $P.F = \frac{\pi a^3}{2} \times c = \frac{2\pi}{3\sqrt{3}} \frac{a}{c} = \frac{2\pi}{3\sqrt{3}} \left[\frac{3}{8}\right]^{\frac{1}{2}} \quad \because \frac{c}{a} = \sqrt{\frac{8}{3}}$   $= \frac{2\pi\sqrt{3}}{3\sqrt{3}\sqrt{8}} = \frac{2\pi}{3\times 2\sqrt{2}}$  $= \frac{\pi}{3\sqrt{2}} = 0.74 = 74\%$ 

74% of the volume is occupied by the atoms .Remaining 26% is empty.

4. What are miller indices? Explain how they are determined.



Scientist miller introduced a system (set of 3 numbers) to designate a plane in a crystal, is called miller indices of concerned plane.

These are three possible integers which have the same ratios as the reciprocal of the intercepts of the plane concerned along the 3 axes.

For ex. A plane ABC has intercepts of 2 axial units on x-axis, 2 axial units on Y -axis, 1 axial unit on Z-axis. The numerical parameters of this plane are 2,2and 1. Therefore its orientation is (2,2,1).

Miller suggested to describe the plane by the reciprocal of its numerical parameters. i.e [ $\frac{1}{2}$ :  $\frac{1}{2}$ : 1] or

(112).

To get the whole numbers, all three reciprocals are multiplied by 2.

The general expression for miller indices of a plane = (h k L).

Steps to find miller indices:

Find the intercepts of the plane along the coordinates axes X, Y, Z.

Take the reciprocal of these intercepts.

The reciprocal s are multiplied by LCM number.

Write these integers within the parenthesis.

#### 5. Derive an expression to find 'd' spacing in cube lattice.



Consider a cubic crystal . a is side of the cube edge. ABC is a reference plane.

ON is perpendicular to the plane ABC.

OA,OB,OC are intercepts of plane ABC.  $\alpha', \beta', \gamma'$  are the angles between reference axes OX,OY,OZ. Therefore the miller indices of intercepts,

$$OA:OB:OC = \frac{1}{h}: \frac{1}{k}: \frac{1}{l} = \frac{a}{h}: \frac{a}{k}: \frac{a}{l}$$
$$OA = \frac{a}{h}; OB = \frac{a}{k}; OC = \frac{a}{l}$$
$$In \triangle OAN, OBN, OCN,$$
$$\cos \alpha' = \frac{ON}{OA} = \frac{d}{a/h} = \frac{dh}{a}$$
$$\cos \beta' = \frac{ON}{OB} = \frac{d}{a/k} = \frac{dk}{a}$$
$$\cos \gamma' = \frac{ON}{OC} = \frac{d}{a/l} = \frac{dl}{a}$$

The law of - direction - cosines,  

$$\cos^{2} \alpha' + \cos^{2} \beta' + \cos^{2} \gamma' = 1$$

$$\left[\frac{dh}{a}\right]^{2} + \left[\frac{dk}{a}\right]^{2} + \left[\frac{dl}{a}\right]^{2} = 1$$

$$\frac{d^{2}h^{2}}{a^{2}} + \frac{d^{2}k^{2}}{a^{2}} + \frac{d^{2}l^{2}}{a^{2}} = 1$$

$$d^{2} = \frac{a^{2}}{(h^{2} + k^{2} + l^{2})}$$

$$d = \frac{a}{\sqrt{(h^{2} + k^{2} + l^{2})}}$$

### 7. Describe the various types of crystal defects with suitable diagrams.

### **Point defects:**

**1. Vacancies:** When ever one are more atoms are missing from a normally occupied position, the defect caused is known as Vacancy .



**2. Substitutional impurity:** Whenever a foreign atom occupies a position, which was initially meant for the parent atom, the defect is known as substitutional defect.



**3.** Interstitial impurity: Whenever an extra atom occupies interstitial sites namely voids in the crystal , the defect resulted is known as interstitial defect.



- **4.** Frenkel defect: Whenever a missing atom occupies an interstitial position, the defect caused is known as frenkel defect. This defect is more common in ionic crystals.
- **5.** Schottky defect: Whenever a pair of positive and negative ions is missing from a crystal, the defect caused is known as schottky defect.

## LINE DEFECTS:

**1. Edge dislocation:** This misalignment of atoms in a one dimensional array or in a linear way is called as a linear defect or dislocation.

The edge of an extra portion of plane of atoms or half plane terminates within the crystal. This is termed as edge dislocation.



2. **Screw dislocation:** This defect or dislocation is due to shear stress, produced due to the distortion in the upper front region of the crystal that is shifted one atomic distance to the right relative to the bottom portions.



# **Burgers vector:**

It denotes the magnitude and direction of lattice distortion associated with a dislocation.

The magnitude and direction of lattice distortion associated with a dislocation is expressed in terms of a Burgers vector, denoted by 'b'.



### **SURFACE DEFECTS:**

**1. Grain boundary:** Whenever the grains of different orientations separate the general pattern of atoms and exhibit boundary as shown in fig, the defect caused is known as grain boundary.



2. Twin boundary: When the boundaries in which the atomic arrangement on one side of the boundary is a somewhat mirror image of the arrangement of atoms on the other side as shown in fig, the defect caused is known as twin boundary.



3. **Stacking faults:** Whenever the stacking of atoms is not in a proper sequence throughout the crystal, the fault is known as stacking fault.



questions The modulus of elasticity is dimensionally equivalent to	opt1 Strain	opt2 Stress	opt3 Surface tension
If by applying a force, the shape of a body is changed, then the corresponding stress is known as	Tensile stress	Bulk stress	Shearing stress
According to Hooke's law of elasticity, within elastic limits, if the stress is increased, the ratio of stress to strain	Increases	Decreases	Becomes zero
Which one of the following does not affect the elasticity of a substance?	Hammering	Adding impurity in the substance	Changing the dimensions
The bulk modulus of a fluid is inversely proportional to the Shearing strain is given by	Change in pressure Deforming force	Volume of the fluid Shape of shear	Density of the fluid Angle of shear
The ratio of the change in dimension at right angles to the applied force to the initial dimension is known as	Young's modulus	Poisson's ratio	Lateral strain
Which of the following is dimensionless quantity?	Stress	Young's modulus	Pressure
The energy per unit volume of a stretched wire is	1/2 *stress *strain	strain*stress	1/2 *load *extension
Out of the following materials, whose elasticity is independent of temperature?	Copper	Invar steel	gold
Theoretical value of Poisson's ratio lies between	- 1 to 0.5	-1 to -2	0.5 to 1
Strain has	No units but	Only units	No units, no
	dimensions	dimensions	but a constant value
When impurities are added to an elastic substance, its elasticity	Increases	Decreases	Becomes zero
Longitudinal strain is possible in the case of	Gases	Liquid	only solids
When the intermolecular distance increases due to tensile force, then	There is no force between the molecules	There is a repulsive force between the molecules	There is an attractive force between the molecules
If a material is heated and annealed, then its elasticity is	Increased	Decreased	Not change
Hooke's law essentially defines	stress	strain	yield point
The Young's modulus for a plastic body is Which of the following have highest	one	zero	infinity rubber
when of the following have ingliest	50001	copper	100001

Energy in a stretched wire is	Half of load x strain	Half of stress / strain	Stress x strain
The property due to which then sheets can be prepared from a material is called	Elasticity	Brittleness	Malleability
The substance which shows practically no elastic effect is	Quartz	Copper	silk
In uniform bending experiment ,which property can be calculated	Rigdity modulus	youngs modulus	bulk modulus
In torsional pendulam experiment ,which property can be calculated	Rigdity modulus	youngs modulus	bulk modulus
The property by virtue of which a deformed body tends to regain its original shape after the removal of deforming forces is called	Elasticity	Plasticity	Rigidity
Restoring force per unit area is given by	Stress	Strain	Modulus
Unit of stress is	Nm^-2	Nm^2	Nm^3
Unit of strain is	Metre	Metre^3	No unit
Based on Hookes law stress is directly proportional to	Modulus	Strain	Stress
Young's modulus = Longitudinal stress/	Longitudinal strain	Lateral strain	Shearing strain
The ratio of tangential stress to shearing strain is	Young's modulus	Rigidity modulus	Bulk modulus
Volume stress/volume strain is known as	Poisson's ratio	Bulk modulus	Rigidity modulus
Relationship between three modulli of elasticity is	3K+G/ 9Gk	9GK/ 3k+G	9Gk/9G+K
A rod of uniform cross section with greatest length is known as	Bar	Beam	Cantilever
If a beam fixed horizontally at one end and loaded at the other end is known as	Bar	Cantilever	Support
Poisson's ratio =	lateral strain/ longitudinal strain	lateral stress /lateral strain	longitudinal stress/strain
What is the ratio of stress to tensile strain called?	Poisson's ratio	Pascal law	Hooke's law
What is the SI unit of pressure?	Nm	Nm^-1	Nm^-2
What is the density of air?	1.3	13.6	9.23

opt4	opt5	opt6	answer
Poisson's ratio	_	_	Stress
Compressive			Shearing
stress			stress
Remains			Remains
constant			constant
Change of			Changing the
temperature			dimensions
to the state of th			
Change in its			Change in its
volume			volume
Change in			Angle of
volume of			shear
hody			Shear
			т. 1
Shearing strain			Lateral
			strain
~ .			~ .
Strain			Strain
load*			1/2 *stress
Extension			*strain
Silver			Invar steel
1 to 2			- 1 to 0.5
NT			NT
No units, no			No units, no
dimensions			dimensions
but a variable			but a variable
value			value
May increase			May increase
or decrease			or decrease
Only gases &			only solids
liquids			
There is			There is an
zero resultant			attractive
force between			force between
the molecules			the molecules
Becomes zero			Decreased
elastic limit			elastic limit
less than one			zero
aluminium			steel

Load / strain	Half of load x strain
Ductility	Malleability
Rubber	Quartz
none	youngs
	modulus
none	Rigaity
Moldity	Elasticity
Shearing strain	Stress
Nm^-1	Nm^-2
Stress	No unit
Elasticity	Strain
Bulk strain	Longitudinal
	strain
Poisson's ratio	Rigidity
	modulus
Young's	Rigidity
modulus	modulus
3K-2G/6K+2G	9GK/ 3k+G
support	Beam
Beam	Cantilever
stress/strain	lateral strain/
	longitudinal
	strain
Youngs	Youngs
modulus	modulus
Nm^-3	Nm^-2
123.32	1.3

S.NO	QUESTIONS
1	The frequency of ultrasonic waves is
2	The ultrasonic waves are frequency waves
3	The ultrasonic waves are to human ear
	The ultrasonic has many advantages based on the principle that sound waves are
4	at the boundary of two surfaces.
5	which one of the method used for production of ultrasonic waves?
6	is the principle used for the production of ultrasonic waves.
7	Which one of the following is the ferromagnetic material ?
	When a coil is wounded over a vibrating rod thenwill be induced in
8	the coil.
9	Magnetostriction generator can produce frequency upto
10	is the example of piezo-electric crystal.
11	Quartz crystal has shape with pyramids attached at both ends.
12	Electrical axis in a crystal is otherwise known as
13	Optical axis in crystal is known as
14	Mechanical axis in a crystal is known as
15	When the crystal is cut perpendicular to y-axis is
16	Y-cut crystal produces ultrasonic waves.
	is the priciple behind the production of ultrasonic waves using piezo-
17	electric oscillator circuit.
18	The piezo-electric generator can produce frequency
19	The production of ultrasonic waves is temperature.
20	When ultrasonic waves passes through liquid it produces wave pattern
	When ultrasonic waves passed through a liquid, its density varies due to variation
21	in pressure and hence the liquid act as
22	The acoustic grating method is used to measure of the ultrasonic waves.
23	.Based on principle the ultrasonic waves are used in SONAR.
	is used to examine the material to detect imperfections and properties
24	without damaging the material.
25	In NDT the time consumption is
26	is the principle used in ultrasonic flaw detector.
27	A-scan display gives information about the specimen.
28	A-scan method is used to detectand of flaws.
29	Brightness mode (or) B-scan display gives a image.
30	B-scan provides exact information about structures of the specimen.
31	TM scan display gives images of the specimen
32	When sound interacts with materials and boundaries, it displays all properties of
33	Both bats and dolphins have ability to "see" using
34	Soft materials absorb large amount ofheat energy
35	Echo of sound is more prominent if surface is
36	Velocity (speed) of sound is
37	What is the Speed of sound in air?
38	Sound can be produced by
39	Loudness and pitch are determined by and respectively.

	Bending of light as it passes from one medium to another is called
40	

OPT 1	OPT 2	OPT 3	OPT 4
> 20,000	< 20,000	20-20,000	10,000 only
low	.medium	high	normal
inaudiable	audible	pleasant	noise
refracted	absorbed	diffracted	reflected
kundts tube method	thermal method	NDT method	galton whistle method
negative local pressu	magnetostriction effect	piezo electric effect	both a&c
cobolt	cupper	ZINC	aluminium
voltage	resistance	e.m.f	current
10 MHz	2Mhz	3 M Hz	5MHz
nacl	kcl	quartz	ferromagnetic rod
.hexagonal	triangle	circle	cube
y-axis	x-axis	z- axis	x and y
z-axis	x-axiz	y-axis	x and y
optic axis	z-axis	x- axis	x or y
y cut crystal	x cut crystal	z cut crystal	none
longitudinal	vertical	horizontal	traverse
piezo-electric effect below 500 Mhz	magnetostriction effect	stark effect	inverse piezo electric effe
dependent	normal	constant	independent
stationary	longitudinal	transverse	nlane
Stutionary	Iongitualitat		.prune
diffraction grating	acoustical grating	both a&b	none
velocity	density	temperature	pressure
echo sounding	negative local pressure	coagulation	superposition
NDT	DT	SONAR	LASER
zero	high	low	moderate
.change in volume	change in medium	change in temperature	change in pressure
1D	3D	2D	none
position & size	pressure & volume	temperature &velocity	density &viscosity
3D	4D	1D	2D
external	internal	tranverse	longitudinal
3D	2D	1D	none
heat	waves	light	electricity
electric waves	heatwaves	sound waves	lightwaves
heat energy	light energy	EM waves	sound energy
soft	rigid	porous	smooth
1/frequency	wavelength/frequency	frequency x wavelength	frequency
343m/s	340m/s^2	330m/s	300m/s
vibration	angular motion	transverse motion	lontgitudinal motion
timbre and quality	Amplitude and Frequency	wavelength and frequence	frequncy only

reflection	refraction	rarifaction	difraction

ANS	
> 20,000	1
high	3
inaudiable	1
reflected	4
galton whistle meth	4
both a&c	4
cobolt	1
e.m.f	3
3 M Hz	3
quartz	4
.hexagonal	1
x-axis	2
z-axis	1
y-axis	4
y cut crystal	1
traverse	4
inverse piezo electri	4
upto 500Mhz	2
independent	4
stationary	1
J	
diffraction grating	3
velocity	1
echo sounding	1
0	
NDT	1
low	3
change in medium	2
1D	1
nosition & size	1
2D	4
internal	2
3D	1
waves	
sound waves	
sound energy	
rigid	
frequency x waveler	ngth
343m/s	
vibration	
Amplitude and Freq	uency

refraction	

questions         If there is no transfer of energy between two objects then their temperature is         Heat is transferred in solids by         Bad conductors are also called	opt1 same radiation insulators
Heat is measured in	joule Compressor and
In a refrigeration system, the expansion device is connected between the Quantity of thermal energy absorbed by a body for 1 kelvin increase in its	condenser
temperature is known as Gaps are left in railway tracks to compensate thermal expansion during	heat capacity rainy season
An increase in breadth, length and thickness of a substance is due to The coefficient of thermal conductivity of a rubber can be determined by the	fusion
principle of flow of heat.	Rectilinear
Lee's method for bad conductors a steady current passed through	1
·	heater coil ratio of thermal conductivity to thermal capacity per
Thermal diffusivity is defined as	unit volume
Thermal capacity of a good conductor is determined by Which of the following has highest heat capacity?	Lee's method metal Dulong and
Thermal capacity of a good conductor is determined by Which of the following has highest heat capacity? Which law gives the relation between the work done and the heat produced?	Lee's method metal Dulong and petit's law zero
Thermal capacity of a good conductor is determined by Which of the following has highest heat capacity? Which law gives the relation between the work done and the heat produced? Molecules of a solid vibrate with larger amplitude at Heat is transferred in gases by	Lee's method metal Dulong and petit's law zero temperature radiation
Thermal capacity of a good conductor is determined by Which of the following has highest heat capacity? Which law gives the relation between the work done and the heat produced? Molecules of a solid vibrate with larger amplitude at Heat is transferred in gases by Which of the following is not a common microwave application? Microwave oven operates at a frequency of During a refrigeration cycle,heat is rejected by the refrigerant in a One tonne of refrigeration is equal to	Lee's method metal Dulong and petit's law zero temperature radiation radar 1.37 GHz Condenser 21/kJ/min
Thermal capacity of a good conductor is determined by Which of the following has highest heat capacity? Which law gives the relation between the work done and the heat produced? Molecules of a solid vibrate with larger amplitude at Heat is transferred in gases by Which of the following is not a common microwave application? Microwave oven operates at a frequency of During a refrigeration cycle,heat is rejected by the refrigerant in a One tonne of refrigeration is equal to Air refrigeration cycle is used in Which of the following refrigerant is highly toxic and flammable Which of the following refrigerant has the lowest boiling point? What is the principle of domestic refrigerator? The ceramic oven is constructed using	Lee's method metal Dulong and petit's law zero temperature radiation radar 1.37 GHz Condenser 21/kJ/min Commercial refrigerators Ammonia zeroth law Clay less than

	the exit temperature of hot fluid is always equal to the exit
In parallel flow heat exchangers,	of cold fluid
For the same heat transfer Q and same overall heat transfer coefficient Uo, surface area required for parallel flow operation is always	LMTD for counter flow smaller than
For the same inlet and exit temperatures of two fluids, the LMTD for counterflow is always	LMTD for parallel flow
Which of the following temperature difference is safer than other to consider in designing of heat exchangers?	Arithmetic Mean Temperature Difference when the temperature profiles of
When is the arithmetic mean temperature difference of heat exchanger used instead of LMTD?	two fluids of heat exchanger are sloping downward with curve the arithmetic mean temperature difference is less than
How can the arithmetic mean temperature difference and LMTD of a same heat exchanger be compared?	LMTD of a same heat exchanger Mechanical
The response of a material due to the function of heat is known as Tendency of matter to change in shape, area, and volume in response to a change in a particular temperature is called	property non linear expansion mechanical and electrical
Internal energy comprises of two types of energies, those are	energy
A pure substance would freeze or solidify at its	boiling point

	Color and
Which of following does not belong to list of factors that affect rate of transfer	texture of
of energy by radiation?	the surface
	increasing
	the surface
Rate of transfer of energy by radiation can be increased by	temperature
	Conduction
Vacuum in a vacuum flask prevents heat transfer through process of	only
	Solids <
With respect to heat transfer through conduction, which of following	liquids <
inequalities place solids', 'liquids' and 'gases' in right order?	gases
A perfect black body is one which all the radiations.	Absorbs
The classical theory was not able to explain the	diffraction
The discrete energy values in the form of quantum of definite frequency are call	phonons
Which of the following are not affected by the magnetic field?	electrons
The relation between energy and the momentum of the photon is	P=EC
The wave associated with a material particle are called as	standing wave
De-Broglie wavelength in terms of energy is	h/2mE
De-Broglie wavelength in terms of voltage is	h/2mV
According to theory the hydrogen spectrum is a continuous spect	classical
According to theory the hydrogen spectrum is a discrete spectrum	classical
The de-Broglie wavelength of an electron of energy 100 eV is	12 27 Angstro
In one dimensional potential box the potential energy of the electron inside the h	maximum
According to quantum mechanics, the energy levels of an electron are	continuous
Source used in the SFM is	electrical enre
Knowledge of the wave function of a particle enables the probabilities of the particle enables the particle enables the probabilities of the particle enables the particle enable	narticle's m
The speed of propagation of an electromagnetic wave in vacuum is:	$3 \times (10)^{6} m$
The expression of the momentum of a photon is :	n = h * lamda
If the uncertainty of a proton accelerated in a laboratory is $400 \text{ m/s}$ that of its po	7.88  nm
Planck's constant has the same units as	angular mome
Which of the following is known as the Schrodinger equation ?	E = h* nu
The principle that all microscopic physical entities have both years and particle :	
In the principle that an incroscopic physical entries have both wave and particle j In the probabilistic interpretation of wave function $\Psi$ the quantity $ \Psi  \wedge 2$ is:	a probability
Overtum Machanics is also called as	Classical Maa
Classical Machanics failed to avalain	Thomas dumon
Ouestical Mechanics failed to explain	May Dlagal
As terms returns increases, the neal succession of the distribution of the distributio	
As temperature increase, the peak wavelength emitted by the black body	Increases
As temperature increase, the total energy emitted by black body	No Change
According to de-braglie wave equation, when mass of the particle decreases way	Decreases
Speed of Light	$3 \times (10)^{18} \text{ m/s}$
A particle in one dimensional box at the walls of the box potential Energy will b	Increases
Photons propagate with speed of light.	smaller
According to de-broglie wave equation, when mass of the particle increases wav	Decreases
Black body emits radiation in	visible region
According to plancks quantum theory, electrons in the black body radiator are as	selectric oscilla

The black body radiator emits energy in	discrete		
The term kB represents	Bohr radius		
Expression for momentum is	p = 2 m v		
(Delta) <sup>2</sup> represents	Hermition ope		
Relation between angular and linear frequencies is	omega = nu/2		
Which one of the following is true?	nu= p/lamda		
For a free particle, potential energy is	0		
According to de-broglie wave equation, when velocity of the particle increases w Doubles			
A particle in one dimensional box at the walls of the box wave function will be Increases			
Energy of photon is directly related to the	wavelength		
Calculate the minimum uncertainty in velocity of an electron trapped in 30.3nm	1.20 x 10^4 m		
Frequency below which no electrons are emitted from metal surface is	_minimum freq		
Loss of energy of an electron results in	absorption of		
Electrons show diffraction effects because their de Broglie wavelength is similar	r spacing betwe		
Wavelength of ultraviolet region of electromagnetic spectrum is	121 nm		
A perfect black body is a perfect absorber and radiator of radiation	monochromat		

opt2 different convection convectors	opt3 zero conduction radiators	opt4 infinite fusion termaids	opt5	opt6	answer same conduction insulators
kelvin	celsius	joule second			joule
Condenser and receiver pressure	Receiver and evaporator	Evaporator and compressor potential			Receiver and evaporator
capacity winter thermal	Kinetic energy hot season	energy wind			heat capacity hot season thermal
expansion	stress	boiling			expansion
Cylindrical	Radial	Axial			Cylindrical
thermo couples	thin disk	copper plates			heater coil
directly proportional to the thermal conductivity	inversely proportional to thermal conductivity	directly proportional to the square of the thermal conductivity			ratio of thermal conductivity to thermal capacity per unit volume
Forbe's method soil	searle's apparatus water	method air			Lee's method water
Newton's law lower temperature convection	Kirchoff's law higher temperature conduction	Joule's law pressure fusion			Joule's law higher temperature convection
mobile radio 1.45 GHz Compressure 210/kJ/min Domestic refrigerators	telephone 2.45 GHz Evaporator 420/kJ/min Air- conditioning	communication 3.94 GHz Expansion valve 620/kJ/min Gas liquefaction	2		mobile radio 2.45 GHz Condenser 210/kJ/min Gas liquefaction
Carbon dioxide Carbon dioxide First law Glass more than	Sulphur dioxide Sulphur dioxide Second law Plastics	Freon-12 Freon-12 third law Rubber			Ammonia Carbon dioxide Second law Clay less than
LMTD for parallel flow	same as LMTD for parallel flow	unpredictable			LMTD for parallel flow

the exit	the exit	we cannot	the exit
temperature of	temperature of	predict	temperature
hot fluid is	hot fluid is	comparison	of hot fluid is
always less	always more	between exit	always more
than the exit	than the exit	temperatures	than the exit
temperature of	temperature of	of hot fluid	temperature
cold fluid	cold fluid	and cold fluid	of cold fluid
more than			more than
LMTD for	same as LMTD		LMTD for
counter flow	for counter flow	unpredictable	counter flow
greater than			greater than
LMTD for	same as LMTD		LMTD for
parallel flow	for parallel flow	unpredictable	parallel flow
Logarithmic			Logarithmic
Mean			Mean
Temperature	Both have		Temperature
Difference	nothing to do		Difference
(LMTD)	with safety	Other	(LMTD)
when the			when the
temperature	when the	when the	temperature
profiles of two	temperature	temperature	profiles of
fluids of heat	profiles of two	profiles of two	two fluids of
exchanger are	fluids of heat	fluids of heat	heat
sloping upward	exchanger are	exchanger are	exchanger
with curve	straight	quadratic	are straight
			the
the arithmetic	the arithmetic	the arithmetic	arithmetic
mean	mean	mean	mean
temperature	temperature	temperature	temperature
difference is	difference and	difference is	difference is
more than	LMTD of a	double than	more than
LMTD of a	same heat	LMTD of a	LMTD of a
same heat	exchanger are	same heat	same heat
exchanger	equal	exchanger	exchanger
Electrical	Chemical	Thermal	Thermal
property	property	property	property
electrical	thermal	mechanical	thermal
expansion	expansion	expansion	expansion
momentia		kingtig and	trinatia and
magnetic and	1	kinetic and	Kinetic and
electrical	kinetic and	magnetic	potential
energy	potential energy	energy	energy
condensation	1.	sublimation	1.
point	melting point	point	melting point

	Movement of		Movement
Temperature	air above the		of air above
of the surface	surface	Surface area	the surface
	using shiny		
	white surfaces		
	instead of dull	decreasing the	increasing
decreasing the	and black	atmospheric	the surface
surface area	surfaces	pressure	temperature
			Conduction
Convection	Conduction		and
only	and Convection	Radiation only	Convection
·		-	Solids >
Solids < gases	Solids > gases	Solids >	liquids >
< liquids	> liquids	liquids > gases	gases
emits	absorbs and emits	reflects	absorbs and emits
interference	emission of black	scattering	emission of black body ra
photons	neutrons	scattering	photons
protons	photons	positive ions	photons
E=P/C	C=EP	E=PC	E=PC
progressive wave	transverse wave	matter wave	matter wave
h/sqrt(2mE)	h/2mEe	h/2m	h/sqrt(2mE)
h/2mE	h/2m	h/sqrt(2meV)	h/sqrt(2meV)
quantum	Electro magnetic	wave	classical
quantum	electro magnetic	electro magnetic	quantum
122.7 Angstrom	1.227 Angstrom	0.1227 Angstrom	1.227 Angstrom
minimum	zero	infinity	zero
discrete	scattering	diffraction	discrete
chemical source	electron gun	neutron gun	electron gun
particle's energy	particle's mass	The sum of the forces on the particle	particle's mass
3 x (10)^8 m/s	3 x (10)^8 km/s	3 x (10)^ (-8) km/s	3 x (10)^8 km/s
p = h / lamda	p = c/lamda	p = c*lamda	p = c/lamda
9.70 nm	112 nm	115nm	7.88 nm
the Hamiltonian	frequency	de Broglie wavelength	angular momentum
$E = m^* (c)^2$	H* Psi = E* Psi	lamda = h/p	$H^* Psi = E^* Psi$
duality	triality	infinality	duality
a probability amp	1	0	a probability density
Wave mechanics	Statistical mechai	Newtonian mechanics	Wave mechanics
Electromagnetic	Atomic Spectra	Velocity of Particle	Atomic Spectra
De-Broglie	Newton	Einstein	Max Planck
No Change	Decreases	Saturates	Decreases
Decreases	Saturates	Increases	Increases
Increases	Doubles	Zero	Increases
(2.5)×(10)^8 m/s	(3.5)×(10)^8 m/s	2×(10)^8 m/s	3× (10)^8 m/s
Decreases	Zero	infinity	infinity
greater	equal	same	same
Increases	Doubles	Zero	Decreases
single wavelengt	Discrete wavelen	All wavelengths	All wavelengths
harmonic oscilla	simple pendulum	non-linear oscillators	harmonic oscillators

continuos pulse wave Plancks constant Boltzmann consta Stefans constant p = h \* nu $p = h^{*}(nu)/c$ p = m vLaplacian operat Energy operator Hamiltonion operator omega = 2\*pi/nu omega = 2\*pi\*nu nu= 2\*pi\*omega nu= c/lamda lamda = nu\*clamda = 1/nu1 2 3 Increases Decreases Zero Zero infinity Decreases frequency amplitude wave number 2.87 x 10<sup>4</sup> m/s 1.20 x 10<sup>6</sup> m/s 1.20 x 10<sup>5</sup> m/s angular frequenc maximum frequent hreshold frequency emission of phot destruction of photom no. of atomic lay nature of atomic lpositioning of atomic layers 120 nm 119 nm 130 nm polychromatic all wavelengths (coherent

discrete Boltzmann constant p = m vLaplacian operator omega = 2\*pi\*nu nu= c/lamda 0 Decreases Zero frequency 1.20 x 10^4 m/s threshold frequency emission of photon spacing between atomic la 121 nm all wavelengths of

diation

ayers

questions	opt1	opt2
The laser beam from laser source has frequency upto		
leads to many scientific applications.	109HZ	109KHZ
The angular spread (or) divergence of a laser beam is	lm/m	I μm/m
	polychrom	nat in
The laser source emitting radiation are	atte III	nbase
	nature	extradinar
In a given light beam containing wave trains of same frequency are in	ordinary	v light
phase means that light beam is .	light beam	beam
	high	lass
	intense &	intense &
The spontaneously emitted photons are	incoherent	coherent
During population inversion, the number of atoms in excited state can be	meeneren	negative
made more than ground state only under	high	temperatur
condition.	pressure	e
		direct
The method of pumping used in Carbon dioxide laser	optical	electron
is	pumping	excitation
Active centre of Carbon diavide loser is	s halium	water
	æ nenum	P-N
Active medium of homo juction semiconductor laser		iunction
is .	silicon	diode
		P-N
Active centre of hemojuction semi conductor laser		junction
18	neon	diode
	8400 μm	04004
The wavelength of laser beam emitted by homojuction semiconductor	- 8600	8400A-
laser source is	μΠ	silver
Which of the following act as a optical resonator of homoiuction	metallic	coated
semiconductor laser?	mirror	mirrors
	high	low
Gallium Arsenide acts as optical resonator in homojuction semiconductor	r refractive	refractive
laser due to its	index	index
The method of pumping used in heterojunction semiconductor laser	optical	chemical
is	pumping	process
The wavelength of laser beam emitted by heterojunction semiconductor		5005 ·
laser 1s	6382 A	5892 A
The wavelength of laser beam emitted by the Callium Arganida		
semiconductor laser is its hand gap is 1.44 eV	ν 5892 Δ	1.06 um
	507211	1.00 µIII

The wavelength of laser beam emitted by the GaAlAs laser is		
, its band gap is 1.55 eV.	5892 A	1.08 µm
The method of pumping used in homojunction semiconductor laser	direct	optical
is	pumping	pumping

The wavelength of the laser beam emitted by a semiconductor laser depends on	biasing voltage across the junctions	band gap
Due to property laser is used to destroy tumors.	highly intense	directional ity
Due to property laser is used to do micro surgery.	highly intense	directional iy high
Due to property, laser is used in endoscopic applications.	directional ity	penetratin g power single wavelengt
The term "monochromatic" means	inphase inphase with same	h single wavelengt
The term "coherence" means	frequency spontaneo us	h stimulated
Which of following parameter induces the lasing action? The angular spread at ordinary light is	emission 1mm/m dependent of incident	emission 1m/m independe nt of incident
Spontaneous emission is random and	radiation low	radiation
Underthe population of energy levels obey the Boltzmann's distribution law.	temperatur e	high pressure
Spontaneously emitted photons are	inphase	not inphase
In stimulated emission, the emitted photons are	not inphase	random in direction
The medium in which the population inversion takes place.	active centre	active medium
---	----------------------	------------------------
A photon incident on the excited atoms in the active medium and initia the	tes absorption	stimulated emission
excited state the is achieved	action	nonulation
The more number of atoms stimulated from excited state to the ground	laser	population
state is achieved.	action	inversion plane
Brewster windows produces theby reflection, of perpendicularly polarized light.	population inversion	polarised light
The output nature of Carbon dioxide laser is	continuous	pulsed
	the	the
	diameter	diameter
	of the	of the
The output power of the Carbon dioxide laser is increased by	discharge tube	discharge tube
The band gap energy of the homojunction semiconductor laser is		
	1.55eV	1.44MeV
The band gap energy of the hetrojunction semiconductor laser is	1 55eV	1 44MeV
	1.550 V	1.111010 1
	directional	highly
Due to property the laser is used in drilling proce	ess. ity	intense
The output power of the Ga-As laser is	1.8W	1.8mW
	Radio	microwav
Which carrier wave is capable of carrying more information's?	waves	es
The central portion of optical fiber consists of	. Cladding	core
The refractive index of the core isthan cladding	5	
surface of optical fiber.	Greater	below
	strengthing	g strengthin
Polyurethane is used as	material	g material
	Outer	strengthin
layer traps the escaping light from the core.	jacket	g material
The optical fibers has band width.	High	low
The optical fibers has loss.	Maximum	minimum
The principle of optical fiber communication is	Refractior	diffraction
The diameter of the core in single mode fibers are m mode fibers.	ulti Smaller than	larger than

	more than 50 MHz	less than 50MHz
The band width of single mode fiber is	Km	Km
		graded
In general the single mode fibers are fibers.	Step index	index
The path of light propagation in graded index fiber is	Zigzag	helical
In photodiode, the electron hole pair is created due to the of photon.	Emission	absorption
The unit of Numerical Aperture is	No unit	decibel
communication can be made even in the absence of	Radio	microwav
power.	wave	e
In the fiber communication, the optical signals are by		not
electric signals, (lightening).	Affected	affected

opt3	opt4	opt5	opt6	answer
1014KHZ 1mm/m	1014HZ 1cm/m monochromati			1014HZ 1mm/m monochroma
monochroma tic in nature	c,coherent in nature			tic,coherent in nature
laser light beam	monochromati c light beam			laser light beam
less intense &incoherent	monochromati c & coherent			less intense &incoherent
low pressure	high temperature			negative temperature direct
direct conversion	chemical method mixture of Carbon			electron excitation
Carbon dioxide	dioxide and nitrogen N-type			Carbon dioxide P-N
P-type semi conductor	semiconducto r			junction diode recombinatio
silicon	of electrons and holes			n of electrons and holes
6382 A	6485 A polished-			8400A- 8600A polished- junction of
P-N junction	diodes high			diodes high
high	reflecting			refractive
conductivity	property			index
inelastic	direct			optical
collision	pumping			pumping
1.06 A	8000 A			8000 A
5892 A	8626 A			8626 A

8626 A	8014 A	8014 A
chemical	elastic	direct
pumping	collision	pumping
		band gap
the	band gap and	and the
concentratio	the	concentratio
n of donar	concentration	n of donor
and	of donor and	and
acceptor	acceptor	acceptor
atoms in an	atoms in an	atoms in an
active	active	active
medium	medium	medium
high		high
nenetrating	not absorbed	nenetrating
power	by water	nower
high	oy water	power
penetrating	not absorbed	
power	by water	directionaliy
highly	narrow band	highly
intense	width	intense
		single
directional	intense	wavelength
		inphase
	less angular	with same
intense	spread'	frequency
	1	1 5
stimulated	spontaneous	stimulated
absorption	absorption	emission
1cm/m	$10^{-3}$ m/m	1m/m
frequency	intensity of	independent
of incident	incident	of incident
radiation	radiation	radiation
high	thermal	thermal
temperature	equilibrium	equilibrium
-	not inphase	not inphase
	and	and
incoherent	incoherent	incoherent
highly		highly
coherent		coherent
and		and
monochroma		monochroma
tic	polychromatic	tic

optical		active
resonator	vacuum	medium
	stimulated	
spontaneous	spontaneous	stimulated
emission	emission	emission
population		population
spontaneous	pumping	inversion
emission	pumping	laser action
	hb2	plane
un polarised		polarised
light	pumping	light
continuous	continuous(or	continuous(o
& pulsed	)pulsed	r)pulsed
		increasing
increasing		the diameter
the pressure	increasing the	of the
of active	pressure of	discharge
medium	active centre	tube
1.44eV	1.55MeV	1.44eV
1.44eV	1.55MeV	1.55eV
	high	high
narrow band	penetrating	penetrating
width	power	power
lmW	IW	lmW
light waves	sound waves	light waves
strengtning	outer jacket	core
material	Salor Jucket	0010
similar	dissimilar	Greater
outer jacket	core	outer jacket
aladding	2070	Outer inclust
zero	Very parrow	High
zero	1	minimum
total	1	total
internal		internal
reflection	reflection	reflection
	non-linear	
	with respect	
same as	to	Smaller than

less than	Less than 50	more than
50KHz Km	KHz Km.	50 MHz Km
	either step	
Step &	(or) graded	
graded index	index	Step index
circle	straight line	helical
both		
emission		
and		
absorption	interference	absorption
meter	Hz	No unit
optical		optical
wave slightly	matter wave	wave
affected	transmitted	not affected

questions	opt1	opt2	
The boundary separating the two adjacent grains is called			
	crystal	x-rays	
The example of amorphous solids is	plastic	nickel	
The example of crystalline solids is	gold	rubber	
Crystalline material is	anisotrophic	isostrophic	
Non crystalline material is	anisotropic imaginary	isotropic	
The lattice means	concept	real concept	
Space lattice is	3-dimensional	2-dimensional	
The example of basis is	aluminium	platinium	
The crystal structure is	lattice+basis	basis+molecule	
	smallest	largest geometr	ic
The unit cell is	geometric figure	figure	
The primitive cell is	one lattice point	two lattice point	t
The example of primitive cell is	SC	BCC	
The crystal system is	7	,	8
The crystal parameters of triclinic crystal system is	a+h+c	a≁h-c	
The lattice parameters of monoclinic crystal system is	af bf c	a≠b−c	
	a≠b≠c	a≠b≠c	
	α=β=γ=900	α ≠ β= γ=900	
The lattice parameters of tetragonal crystal system is			
 The lattice parameters of hexagonal crystal system is	a=b≠c	a≠b≠c	
	α= β =900	α ≠β ≠ 900	
The number of Bravais lattice of triclinic system is	1		2
The number of Bravais lattice of monoclinic system is	-		-
 The number of Bravais lattice of terragonal system is	T		Ζ
 The number of Bravais lattice of hexagonal system is	2	-	1
	1	L	2
The number of Bravais lattice of trigonal system is	1		2
The number of Bravais lattice of cubic system is	- -		2
	3	; 1	2
The number of Bravais lattice is	4	ł	/

The total number of atoms present in (or)shared by an atoms is called\_\_\_\_\_

effective number atomic radius

is the number of nearest neighbouring			
atoms to a particular atom.	atomic number	atomic mass	S
Atomic packing factor is	v/V	V/v	
The total number of atoms per unit cell in SC is			
		2	1
The total number of atoms per unit cell in BCC is		4	2
The total number of face centre atoms per unit cell in ECC		1	3
is		2	1
The total number of atoms per unit cell in FCC is		-	_
 The number of body centre atoms per unit cell is		1	2
 The atomic radius of SC structure is	a/2	4 a/4	3
	- ,	-,	
The atomic radius of BCC structure is	a/2	a/4	
The atomic radius of FCC structure is	a/2	a/4	
The co-ordination of SC structure is		4	2
The co-ordination number of BCC structure is			
		4	6
The co-ordination number of the FCC structure is		10	12
Atomic packing factor for BCC structure is		10	12
	0.	68	0.78
The APF for SC structure is	0.	68	0.78
The APF of FCC structure is	0.	68	0.78
The volume of 1 atom is	4/3πr2	4/3 πr3	
The number of atoms per unit cell in hexagonal			
		12	8
The co-ordination number of hexagonal structure is			
		12	8
The atomic radius of HCP structure is	a/2	a/4	
The APF of HCP structure is	0.	68	0.74
The total number of diamond cubic structure is			
		4	6
The total number of atoms present in (or)shared by an			
atoms is called	effective numbe	er atomic radiu	IS
An element that can exist in 2 or more forms in the same			

state is called \_\_\_\_\_

polymorphism allotrophy

If the atoms in the solid are not arranged in a perfectly regular manner, it is called	crystal point	crystal defect
The point defect is	schottky defect	grain boundaries
The line defect is	schottky defect	grain boundaries
The surface defect is	schottky defect	edge discolation
The defect which take place due to imperfect packing of atoms during crystallization are known as	line defect	crystal defect

opt3	opt4	opt5	opt6	answer
grain boundary platinum glass	crystallography silver plastic definite			grain boundary plastic gold
sharp melting point regular geometrical	geometrical shape			anisotrophic
shapes	isochoric			isotropic imaginary
regular concept	lattice concept			concept
1-dimensional aluminium lattice+atoms middle geometric figure three lattice	4-dimensional Nacl basis+atoms very largest geometric figure			3-dimensional aluminium lattice+basis smallest geometric figure one lattice
point	four lattice point			point
FCC 6	triclinic	5		SC 7
a=b≠c	a=b=c			a≠b≠c
a=b=c	a=b≠c			a≠b≠c
α= β≠ γ=900	α≠β≠ γ≠900			α=β=γ=900
a=b=c	a≠b=c			a=b≠c
α ≠ β = 900	α =β≠900			α= β =900
3	Δ	1		1
3		1		2
3	Δ	1		2
3	2	1		1
3	2	1		1
4 14	. 1	L 3		3 14

co-ordinations number	cubic system		effective number
atomic weight ν/ ρ	co-ordination number ans-d V/p		co-ordination number ans-d v/V
3		4	1
4		2	2
3		6	3
3		4	4
2		1	1
a/6	a/8		a/2
a * sqrt(3)/4	a/8		a * sqrt(3)/4
a * sqrt(2)/4	a/8		a * sqrt(2)/4
3		6	6
8		10	8
14		8	12
0.74 0.74	0 0	52 52	0.68 0.52
0.74 4/ πr2	0 4/ πr3	52	0.74 4/3 πr3
6		4	6
6		4	12
a/6 0.72	a/8 0.!	52	a/2 0.74
8		10	8
co-ordinations number	cubic system		effective number
crystal	SC		allotrophy

BCC	FCC	crystal defect
edge		
dislocation	screw dislocation	schottky defect
edge		edge
discolation	frenkel defect	discolation
grain		grain
boundaries	frenkel defect	boundaries

point defect surface defect

point defect